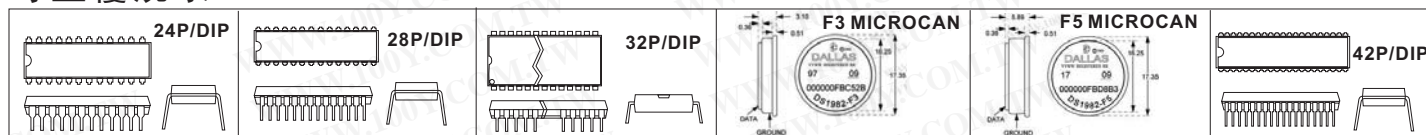


## EPROM记忆体 可重覆烧录 EPROM

详细产品规格 - 请点击 [cn.100y.com.tw](http://cn.100y.com.tw)



100Y 编号	厂商编号	制造商	说明	Size (bits)	words×bits	Access time (nS)	Program Volt.	Pins/Package	Volt.(Vcc)
1469	2716		NMOS 16 KBIT (2KB X8) UV EPROM	16K	2K*8			24P/DIP	5 V
24029	AM27128A-3DC	AMD	EPROM	128K	16K*8		12.5V	DIP/28P	
1415	AM27C010-120DC	AMD	1 Megabit (128 K x 8-Bit) CMOS EPROM	1M	128K*8	120ns	12.75Vpp	32P/DIP	5 V
1416	AM27C020-150DC	AMD	2 Megabit (256 K x 8-Bit) CMOS EPROM	2 M	256K*8	150ns	12.75Vpp	32P/DIP	5 V
18607	AM27C040-120DC	AMD	4 Megabit (512 K x 8-Bit) CMOS EPROM	4M	512K*8	120ns	12.75Vpp	32P/DIP	5 V
1418	AM27C040-95PC	AMD	4 Megabit (512 K x 8-Bit) CMOS EPROM	4M	512K*8	95ns	12.75Vpp	32P/DIP	5 V
16799	AM27C1024-120DC	AMD	1 Megabit (65 K x 16-Bit) CMOS EPROM	64K	8K*8	120ns	12.5Vpp	40P/DIP	5 V
18608	AM27C1024-150DC	AMD	1 Megabit (64 K x 16-Bit) CMOS EPROM	1 M	64 K*16	150ns	12.5Vpp	40P/DIP	5 V
18609	AM27C256-90DC	AMD	256 Kbit (32 K x 8-Bit) CMOS EPROM	256 K	32 K x 8	90ns	12.75Vpp	28P/DIP	5 V
18610	AM27C4096-150DC	AMD	4 Megabit (256 K x 16-Bit) CMOS EPROM	4 M	256 K x 16	150ns	12.75Vpp	40P/DIP	5 V
18611	AM27C4096-95DC	AMD	4 Megabit (256 K x 16-Bit) CMOS EPROM	4 M	256 K x 16	90ns	12.75Vpp	40P/DIP	5 V
22451	AM27C512-120DC	AMD	512 Kilobit (64 K x 8-Bit) CMOS EPROM	512K	64K*8	120ns	12.75Vpp	28P/DIP	5 V
32666	AM27C512-120JC	AMD	512 Kilobit (64 K x 8-Bit) CMOS EPROM	512K	64K*8	120ns	12.75Vpp	32P/PLCC	5V
17174	AM27C512-150DC	AMD	512 Kilobit (64 K x 8-Bit) CMOS EPROM	512K	64K*8	150ns	12.75Vpp	28P/DIP	5 V
18612	AM27C512-90JC	AMD	512 Kilobit (64 K x 8-Bit) CMOS EPROM	512K	64K*8	150ns	12.75Vpp	32P/PLCC	5 V
28389	AM27C64-200DC	AMD	64 K(8 K x 8-Bit) CMOS EPROM	64 K	8 K x 8-Bit	200ns	12.75Vpp	28P/DIP	5V
18642	AM27H010-70DC	AMD	AM27C010 Pin compat	1024 K	128 K x 8	70ns	12.5V	32P/DIP	5V
1424	AM4708DC	AMD	可重覆烧录 EPROM =2708 中古	8K	1K*8		12V	DIP	5V
22572	CY27C256R-120JC	Cypress	CMOS EPROM	256K	32K x 8-Bit	120nS		32P/PLCC	-0.5~7V
33026	DS1982-F3	DALLAS	1-kbit Add-Only iButton	256-bit	4*256-bit		11.5V to 12.0V	F3 MICROCAN	2.8V to 6.0V
33027	DS1982-F5	DALLAS	1-kbit Add-Only iButton	256-bit	4*256-bit		11.5V to 12.0V	F5 MICROCAN	2.8V to 6.0V
33028	DS1990A-F5	DALLAS	Serial Number iButton	48-bit				F5 MicroCan	2.8V to 6.0V
23550	FM27C040Q120	Fairchild							
32193	HN27512G-25	HITACHI	512K (64K*8-bit) UV and OTP EPROM	524288 bits	65536*8-bits	250nS	12.5V	28P/DIP	28P/DIP
47050	HN27C101AG-10	HITACHI	日立_可重覆烧录 EPROM	1M	128K*8-bit	100NS	12.5V	DIP-32	5V
32191	HN27C256AG-12	HITACHI	256K (32*8-bit) UV and OTP EPROM	262144 bits	32768*8-bits	120nS	12.5V	28P/DIP	5V
18408	HN27C4001G-12	HITACHI	4 MBIT (512KB X8) UVE EPROM	4M	512K*8	120ns	12.5V	32P/DIP	5V
18666	HT27C512-70J	HOLTEK	CMOS 64Kx8-Bit OTP EPROM	512K	64K*8	70ns	12.2Vpp	32P/PLCC	5 V
22623	IS27HC010-45W	ISSI	HIGH-SPEED CMOS EPROM	1M	128*8bit	45nS		32P/DIP	-0.6~7V
30885	M27128A-2F1	ST(SGS)	NMOS 128 KBIT (16KB X8) UV EPROM	128K	64K	200ns	12.5Vpp	28P/DIP	5V
1470	M2732A-2F1	ST(SGS)	NMOS 32K (4K x 8) UV EPROM	32K	4K*8	200ns	21Vpp	24P/DIP	5 V
15462	M27C1001-10F1	ST(SGS)	1 MBIT (128KB X8) UV EPROM AND OTP ROM	1M	128K*8	100ns	12.75Vpp	32P/DIP	5V
1441	M27C1001-12F1	ST(SGS)	1 MBIT (128KB X8) UV EPROM AND OTP ROM	1M	128K*8	120ns	12.75Vpp	32P/DIP	5 V
34810	M27C1001-12XF1	ST(SGS)	1 MBIT (128KB X8) UV EPROM AND OTP ROM	1M	128K*8	120ns	12.75Vpp	32P/DIP	5V
31648	M27C1001-15F1	ST(SGS)	1 MBIT (128KB X8) UV EPROM AND OTP ROM	1M	128K*8	150ns	12.75Vpp	32P/DIP	5 V
18670	M27C1001-20F1	ST(SGS)	1 Mbit (128kb x8) UV EPROM and OTP EPROM	1M	128K*8	200ns	12.75Vpp	32P/DIP	5 V
34812	M27C1001-45XF1	ST(SGS)	1 MBIT (128KB X8) UV EPROM AND OTP ROM	1M	128K*8	45ns	12.75Vpp	32P/DIP	5V
34805	M27C1024-10F1	ST(SGS)	1 MBIT (64KB X16) UV EPROM AND OTP EPROM	1M	64K*16	100ns	12.75Vpp	40P/DIP	5V
17022	M27C1024-12F1	ST(SGS)	1 MBIT (64KB X16) UV EPROM AND OTP EPROM	1M	64K*16	120ns	12.75Vpp	40P/DIP	5 V
14160	M27C1024-15F1	ST(SGS)	1 MBIT (64KB X16) UV EPROM AND OTP EPROM	1M	64K*16	150ns	12.75Vpp	40P/DIP	5 V
31086	M27C1024-15XF1	ST(SGS)	1 MBIT (64KB X16) UV EPROM AND OTP EPROM	1M	64K*16	150ns	12.75Vpp	40P/DIP	5V
1440	M27C1024-85F1	ST(SGS)	1 MBIT (64KB X16) UV EPROM AND OTP EPROM	1M	64K*16	85ns	12.75Vpp	40P/DIP	5 V
16607	M27C160-100F1	ST(SGS)	16 MBIT (2MB X8 OR 1MB X16) UV EPROM AND OTP EPROM	16 M	2Mb x 8 or 1Mb x 16	100ns	12.5Vpp	42P/DIP	5V
18649	M27C160-120F1	ST(SGS)	16 MBIT (2MB X8 OR 1MB X16) UV EPROM AND OTP EPROM	16 M	2Mb x 8 or 1Mb x 16	120ns	12.75Vpp	42P/DIP	5 V
12839	M27C160-90F1	ST(SGS)	16 MBIT (2MB X8 OR 1MB X16) UV EPROM AND OTP EPROM	16 M	2Mb x 8 or 1Mb x 16	90ns	12.75Vpp	42P/DIP	5 V
45590	M27C2001-10F1	ST(SGS)	2 MBIT (256KB X8) UV EPROM AND OTP ROM	2M	256K*8	100ns	12.75Vpp	32P/DIP	5 V
18650	M27C2001-10F6	ST(SGS)	2 MBIT (256KB X8) UV EPROM AND OTP ROM	2M	256K*8	100ns	12.75Vpp	32P/DIP	5 V
1443	M27C2001-12F1	ST(SGS)	2 MBIT (256KB X8) UV EPROM AND OTP ROM	2M	256K*8	120ns	12.75Vpp	32P/DIP	5 V
18651	M27C2001-15F1	ST(SGS)	2 MBIT (256KB X8) UV EPROM AND OTP ROM	2M	256K*8	150ns	12.75Vpp	32P/DIP	5 V
18652	M27C2001-15F6	ST(SGS)	2 MBIT (256KB X8) UV EPROM AND OTP ROM	2M	256K*8	150ns	12.75Vpp	32P/DIP	5 V
34813	M27C2001-15XF1	ST(SGS)	2 MBIT (256KB X8) UV EPROM AND OTP ROM	2M	256K*8	150ns	12.75Vpp	32P/DIP	5 V
18653	M27C256B-10B6	ST(SGS)	256 KBIT (32KB X8) UV EPROM AND OTP EPROM	256K	32K*8	100ns	12.75Vpp	28P/DIP	5 V
1444	M27C256B-10F1	ST(SGS)	256 KBIT (32KB X8) UV EPROM AND OTP EPROM	256K	32K*8	100ns	12.75Vpp	28P/DIP	5 V
18654	M27C256B-12F6	ST(SGS)	256 Kbit (32Kb x 8) UV EPROM and OTP EPROM	256K	32K*8	120ns	12.75Vpp	28P/DIP	5V
32189	M27C256B-15F1	ST(SGS)	256 Kbit (32Kb x 8) UV EPROM and OTP EPROM	256K	32K*8	150ns	12.75Vpp	28P/DIP	5V
34823	M27C256B-15XF1	ST(SGS)	256 Kbit (32Kb x 8) UV EPROM and OTP EPROM	256K	32K*8	150ns	12.75Vpp	28P/DIP	5V
34827	M27C256B-45XF1	ST(SGS)	256 Kbit (32Kb x 8) UV EPROM and OTP EPROM	256 Kbit	32Kb x 8	45nS	12.75Vpp	28P/DIP	5V
34825	M27C256B-70C1	ST(SGS)	256 Kbit (32Kb x 8) UV EPROM and OTP EPROM	256K	32K*8	70ns	12.75Vpp	32P/PLCC	5V
34826	M27C256B-70XF1	ST(SGS)	256 Kbit (32Kb x 8) UV EPROM and OTP EPROM	256 Kbit	32Kb x 8	70ns	12.75Vpp	28P/DIP	5V
18655	M27C322-100F1	ST(SGS)	32 Mbit (2Mb x16) UV EPROM and OTP EPROM	32 M	2Mb x16	100ns	12.75Vpp	42P/DIP	5 V
1447	M27C4001-10F1	ST(SGS)	4 MBIT (512KB X8) UV EPROM AND OTP ROM	4M	512K*8	100ns	12.75Vpp	32P/DIP	5 V



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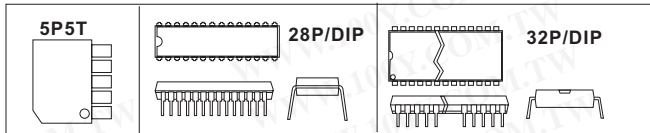
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## 可重覆烧录 EPROM

详细产品规格 - 请点击 [cn.100y.com.tw](http://cn.100y.com.tw)



100Y 编号	厂商编号	制造厂商	说明	Size (bits)	wordsxbits	Access time (nS)	Program Volt.	Pins/Package	Volt.(Vcc)
19590	M27C4001-12F1	ST(SGS)	4 MBIT (512KB X8) UV EPROM AND OTP ROM	4M	512K*8	120ns	12.75Vpp	32P/FDIP	5V
34828	M27C4001-15F1	ST(SGS)	4 MBIT (512KB X8) UV EPROM AND OTP ROM	4 MBIT	512KB X8	150ns	12.75Vpp	32P/FDIP	5V
34829	M27C4001-45XF1	ST(SGS)	4 MBIT (512KB X8) UV EPROM AND OTP ROM	4 MBIT	512KB X8	45nS	12.75Vpp	32P/FDIP	5V
40129	M27C4001-80XF1	ST(SGS)	4 MBIT (512KB X8) UV EPROM AND OTP ROM	4M	512K*8	80ns	12.75Vpp	32P/FDIP	5V
12956	M27C4002-10F1	ST(SGS)	4 Mbit (256Kb x16) UV EPROM and OTP EPROM	4M	256K*16	100ns	12.75Vpp	32P/DIP	5 V
1449	M27C4002-12F1	ST(SGS)	4 MBIT (256KB X16) UV EPROM AND OTP ROM	4M	256K*16	120ns	12.75Vpp	32P/DIP	5 V
18656	M27C4002-80XF1	ST(SGS)	4 Mbit (256KB X16) UV EPROM AND OTP ROM	4M	256K*16	80ns	12.75Vpp	32P/DIP	5 V
34831	M27C4002-90C1	ST(SGS)	4 Mbit (256Kb x16) UV EPROM and OTP EPROM	4 Mbit	256Kb x16	90nS	12.75Vpp	32P/PLCC	5V
12214	M27C512-10F1	ST(SGS)	512 KBIT (64KB X8) UV EPROM AND OTP EPROM	512 K	64K*8	100ns	12.75Vpp	28P/FDIP	5 V
34836	M27C512-12B1	ST(SGS)	512 KBIT (64KB X8) UV EPROM AND OTP EPROM	512 KBIT	64KB X8	120nS	12.75Vpp	28P/PDIP	5V
12215	M27C512-12F1	ST(SGS)	512 KBIT (64KB X8) UV EPROM AND OTP EPROM	512 K	64K*8	120ns	12.75Vpp	28P/FDIP	5V
34833	M27C512-12XF1	ST(SGS)	512 KBIT (64KB X8) UV EPROM AND OTP EPROM	512 KBIT	64KB X8	120nS	12.75Vpp	28P/FDIP	5V
48152	M27C512-15F1	ST(SGS)	512 KBIT (64KB X8) UV EPROM AND OTP EPROM	512 K	64K*8	150ns	12.75Vpp	28P/DIP	5V
34835	M27C512-15XF1	ST(SGS)	512 KBIT (64KB X8) UV EPROM AND OTP EPROM	512 KBIT	64KB X8	150nS	12.75Vpp	28P/FDIP	5V
34837	M27C512-45XF1	ST(SGS)	512 KBIT (64KB X8) UV EPROM AND OTP EPROM	512 KBIT	64KB X8	45nS	12.75Vpp	28P/FDIP	5V
34838	M27C512-70C1	ST(SGS)	512 KBIT (64KB X8) UV EPROM AND OTP EPROM	512 KBIT	64KB X8	70nS	12.75Vpp	32P/PLCC	5V
40217	M27C512-70F1	ST(SGS)	512 KBIT (64KB X8) UV EPROM AND OTP EPROM	512 KBIT	64KB X8	70nS		FDIP28W	
1413	M27C512-90F1	ST(SGS)	512 KBIT (64KB X8) UV EPROM AND OTP EPROM	512 K	64K*8	90ns	12.75Vpp	28P/DIP	5V
28752	M27C64A-12F1	ST(SGS)	可重复烧录 EPROM	512 K	64Kb x8	45ns	12.75V ± 0.25V	28P/DIP	-2~ 7V
1422	M27C64A-15F1	ST(SGS)	64 Kilobit (8 K x 8-Bit) CMOS	64K	8K*8	150ns	12.5Vpp	28P/DIP	5 V
34844	M27C64A-20F6	ST(SGS)	64 Kbit (8Kb x 8) UV EPROM and OTP EPROM	64 Kbit	8Kb x 8	200nS	12.5Vpp	28P/DIP	5V
34847	M27C64A-30F1	ST(SGS)	64 Kbit (8Kb x 8) UV EPROM and OTP EPROM	64 Kbit	8Kb x 8	300nS	12.5Vpp	28P/DIP	5V
1450	M27C801-100F1	ST(SGS)	8 MBIT (1MB X 8) UV EPROM AND OTP EPROM	8M	1M*8	100ns	12.75Vpp	32P/DIP	5 V
46332	M27C801-100F6	ST(SGS)	可重复烧录 EPROM	8M	1M*8	100ns	12.75Vpp	32P/DIP	5V
18658	M27C801-120F1	ST(SGS)	8 MBIT (1MB X 8) UV EPROM AND OTP EPROM	8M	1M*8	120ns	12.75Vpp	32P/DIP	5 V
34848	M27W101-80K6	ST(SGS)	1 Mbit (128Kb x8) Low Voltage UV EPROM and OTP EPROM	1 Mbit	128Kb x8	80nS		32P/PLCC	2.7V to 3.6V
19329	M51957BL	MITSUBISHI	可重复烧录 EPROM					5P5T	2~17V
17150	M5M27C102K-12	MITSUBISHI	1M EPROM 120nS	1M(*16)	65536*16	120nS	12.5Vpp	40P/DIP	5V
19375	MB8516	FUJITSU	可重复烧录 EPROM					DIP	
14204	MBM27C128-20	FUJITSU	EPROM 16K*8 DIP	128K	16K*8	200ns		28P/DIP	5V
22743	MX27C1000QC-15	MXIC	CMOS EPROM	128K*8	1M	150nS	12.5V	32P/PLCC	5V
22744	MX27C256QC-15	MXIC	CMOS EPROM	256K	32K*8	150nS	12.5V	32P/PLCC	5V
22749	MX27C8000QC-12	MXIC	CMOS EPROM	1M*8	8M	120nS	12.5V	32P/PLCC	5V
22750	MX27L2000PC-15	MXIC	CMOS EPROM	256K*8	2M	150nS	12.5V	32P/DIP	2.7~3.6V
18663	NM27C010Q200	N.S	1M-Bit CMOS EPROM	1M	128K*8	200nS	12.75Vpp	32P/DIP	5V
23226	NM27C256Q150	N.S	可重复烧录 EPROM	256K	32K*8	150	12.75Vpp	DIP	5V
1465	NM27C256Q90	Fairchild	262,144-Bit (32K x 8) High Performance CMOS EPROM	256K	32K*8	90nS	12.75Vpp	28P/DIP	5V
23599	NM27C256V150	N.S	High Performance CMOS EPROM	32K * 8	256K	150ns		32P/PLCC	5V+/-10%
18672	NM27C256V200	N.S	262,144-Bit (32K x 8) High Performance CMOS EPROM	262,144	32K*8	200ns	12.75Vpp	32P/PLCC	5V
1467	NM27C512Q150	N.S	EPROM 64K*8 DIP	512K	64K*8	150ns	12.75Vpp	28P/DIP	5 V
1472	NMC27C64Q150	N.S	可重复烧录 EPROM	64K	8K*8	150ns	12.75Vpp	DIP	5V
1473	NMC27C64Q200	N.S	可重复烧录 EPROM	64K	8K*8	200	12.75	DIP	5
18673	P27C220-150V05	INTEL	2M-BIT [256Kx8/128x16] CMOS EPROM	2M	256Kx8 or 128x16	150ns	12.5Vpp	40P/DIP	5V
18674	TMS27C020-12JE	T.I.	PROGRAMMABLE READ-ONLY MEMORIES	2M	256K*8	120ns	12.75Vpp	32P/DIP	5 V
1475	TMS27C020-12JL	T.I.	PROGRAMMABLE READ-ONLY MEMORIES	2M	256K*8	120ns	12.75Vpp	32P/DIP	5 V
18675	TMS27C020-15JL	ST(SGS)	PROGRAMMABLE READ-ONLY MEMORIES	2M	256K*8	150ns	12.75Vpp	32P/DIP	5 V
32188	TMS27C210A-15	T.I.	EPROM	1048576 bits	65536 * 16-bit	150ns	13Vpp	40P/DIP	5V
22854	TMS27C240-10JL	T.I.	4M EPROM	4M	222144 by 16Bit	100nS	13Vpp	40P/DIP	5V
32187	TMS27C240-12	T.I.	4M EPROM	4M	262144 by 16Bit	120ns	13Vpp	40P/DIP	5V
18676	TMS27C256-12JL	ST(SGS)	READ-ONLY MEMORY	256K	32K*8	120ns	12.5Vpp	32P/DIP	5 V
3196	TMS27C512-10JL	T.I.	PROGRAMMABLE READ-ONLY MEMORIES	512K	64K*8	100nS	12.75Vpp	28P/DIP	5V
18677	TMS27PC128-1NL	ST(SGS)	READ-ONLY MEMORY	128K	16K*8	150ns	12.5Vpp	28P/DIP	5 V
1484	UPD27C1024AD-20	NEC	1M-BIT [128K x 8/64K x 16] CMOS EPROM	1M	64K*16	200ns	12.75Vpp	40P/DIP	5 V
15277	W27C257-10	WINBOND	Electrically Erasable EPROM	256K	32K*8	100nS	12Vpp	28P/DIP	5 V
18678	W27C512-45	WINBOND	Electrically Erasable EPROM	512K	64K*8	45ns	12Vpp	28P/DIP	5 V
1433	W27C512-45Z	WINBOND	Electrically Erasable EPROM	512K	64K*8	45ns	12Vpp	28P/DIP	5 V
23150	W27C512P-70	WINBOND	ELECTRICALLY ERASABLE EPROM	64K*8	512K	70nS		32P/PLCC	5V
16558	W27E010-70	WINBOND	1M Electrically Erasable EPROM	128K*8	128K*8	70nS	12Vpp	32P/DIP	5 V
15308	W27E010P-70	WINBOND	1MB Electrically Erasable EPROM	1M	128K*8	70nS	12Vpp	32P/PLCC	5 V



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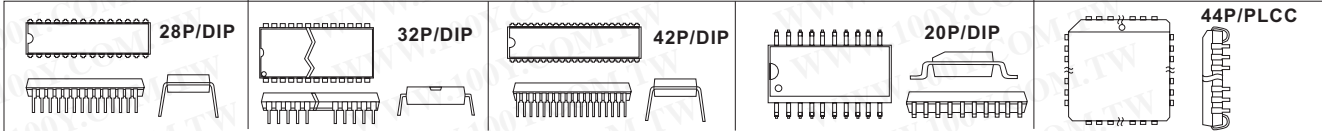
## 可重覆烧录 EPROM

详细产品规格 - 请点击 [cn.100y.com.tw](http://cn.100y.com.tw)

100Y 编号	厂商编号	制造厂商	说明	Size (bits)	wordsxbits	Access time (nS)	Program Volt.	Pins/Package	Volt.(Vcc)
39113	W27E040-12	WINBOND	Electrically Erasable EPROM (Pb Free)	512K	512K*8	120nS		32P/DIP	
39361	W27E040P-12	WINBOND	Electrically Erasable EPROM	512K	512K*8	120		32/PLCC	
1487	W27E257-12	WINBOND	32K x 8 Electrically Erasable EPROM	256K	32K*8	120ns	12Vpp	28P/DIP	5V
39112	W27E512-45	WINBOND	Electrically Erasable EPROM	512K	64K*8	45ns	12Vpp	28P/DIP	5V
1488	W27E512-70	WINBOND	Electrically Erasable EPROM	512K	64K*8	70ns	12Vpp	28P/DIP	5V

## 烧录一次OTP EPROM

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100Y 编号	厂商编号	制造厂商	说明	Access time (nS)	Pins/Package	Program Volt.	Size (bits)	Volt.(Vcc)	wordsxbits
18606	A276308L-70	AMIC	64K X 8 OTP CMOS EPROM	512K	32P/PLCC	70ns	65,536 X 8 bit	12.75V	5V
23517	AM27C010-90DC	AMD	CMOS EPROM	90 ns	32P/DIP		128 K x 8Bit	5 V	1 Megabit
18643	AT27BV010-90JC	ATMEL	1 M Unregulated Battery-Voltage OTP CMOS EPROM	1 M	32P/PLCC	90ns	128K x 812.75V	2.75V	6.25V
1434	AT27BV040-15TC	ATMEL	4-Megabit (512Kx8) Unregulated Battery-Voltage High-Speed OTP EPROM	150ns	32P/TSOP	14Vpp	4M	5 V	512K*8
17681	AT27C020-70PC	ATMEL	2-megabit (256K x 8) OTP EPROM	70ns	32P/DIP	14Vpp	2M	5V	256K*8
1427	AT27C040-90PC	ATMEL	4-Megabit (512Kx8) OTP EPROM	90ns	32P/DIP	14Vpp	4M	5 V	512K*8
15274	AT27C080-10JC	ATMEL	8-Megabit (1Mx8)OTP EPROM	100nS	32P/PLCC	14Vpp	8M	5V	1M*8
22458	AT27C2048-90JC	ATMEL	2-Megabit OTP EPROM	55nS	44P/PLCC	one-time program-mable	2K	5V	128*16
1430	AT27C256R-12PC	ATMEL	烧录一次 EPROM	120ns	DIP		256K	5	32K*8
18645	AT27C256R-25JC	ATMEL	256K (32K x 8) OTP EPROM	25ns	32P/PLCC	14Vpp	256K	5V	32K*8
1432	AT27C512R-12PC	ATMEL	512K (64K x 8) OTP EPROM	120ns	28P/DIP	14Vpp	512K	5V	64K*8
22459	AT27C512R-15TC	ATMEL	512K OTP EPROM	- 45 ns	28P/TSOP	- 100 ms/byte	512K	5V	64*8
18646	AT27C512R-70JC	ATMEL	512K (64Kx8) OTP EPROM	70ns	32P/PLCC	14Vpp	512K OTP	5V	64K*8
18647	AT27C512R-70PC	ATMEL	512K (64Kx8) OTP EPROM	70ns	28P/DIP	14Vpp	512K OTP	5V	64K*8
22460	AT27C512R-70TC	ATMEL	512K OTP EPROM	- 45 ns	28P/TSOP	- 100 ms/byte	512K	5V	64*8
18648	AT27C512R-90JC	ATMEL	512K (64Kx8) OTP EPROM	90ns	32P/PLCC	14Vpp	512K OTP	5V	64K*8
23533	AT27C512R-90PC	ATMEL	OTP EPROM	45 ns	28P/DIP		64K*8	-2~-14V	512K
18664	AT27C512R-90RC	ATMEL	512K (64Kx8) OTP EPROM	90ns	28P/SOIC	14Vpp	512K OTP	5V	64K*8
14361	AT27LV010A-12JC	ATMEL	1-Megabit (128Kx8) Low Voltage OTP EPROM	120nS	32P/PLCC	14Vpp	1M	5V	128K*8
18665	FM27C256Q120	Fairchild	262,144-Bit (32K x 8) High Performance CMOS EPROM	120ns	28P/DIP	12.75Vpp	262,144	5 V	32K*8
18669	ICE27C512-70SC	ICE	512kbit (64Kx8) OTP EPROM	70ns	28P/TSOP	5.5V	512K	12V	64Kx8
18671	M27C160-100B1	ST(SGS)	16 MBIT (2MB X8 or 1MB X16) UV EPROM AND OTP EPROM	100ns	42P/DIP	12.75Vpp	16 M	5 V	2Mb x 8 or 1Mb x 16
15209	M27C2001-15C6	ST(SGS)	2 M OTP ROM	150ns	32P/PLCC	12.75Vpp	2M	5 V	256Kb*8
14954	M27C256B-12F1	ST(SGS)	256 Kbit (32Kb x 8) UV EPROM and OTP EPROM	120ns	28P/DIP	12.75Vpp	256K	5V	32K*8
15273	M27C256B-15C1	ST(SGS)	256 Kbit (32Kb x 8) UV EPROM and OTP EPROM	150ns	32P/PLCC	12.75Vpp	256K	5V	32K*8
23572	M27C256B-80XF1	ST(SGS)	UV EPROM and OTP EPROM	80ns	28P/DIP	12.75V ± 0.25V	32Kb*8	5V ± 10%	256 K
1446	M27C256B-90C1	ST(SGS)	256 Kbit (32Kb x 8) UV EPROM and OTP EPROM	90ns	32P/PLCC	12.75Vpp	256K	5 V	32K*8
38994	M27C4001-12C1	ST(SGS)	4 MBIT (512KB X8) UV EPROM AND OTP ROM	4M	32P/PLCC	120ns	512K*8	12.75Vpp	5V
48659	M27C4001-80N6	ST(SGS)	ST_TSOP-32 烧录一次 OTP EPROM	80nS	TSOP-32	12.75Vpp	4M	5V	512K*8
18657	M27C512-20B1	ST(SGS)	512 KBIT (64KB X8) UV EPROM AND OTP EPROM	200ns	28P/DIP	12.75Vpp	512 K	5V	64K*8
22696	M27V256-100F1	ST(SGS)	LOW VOLTAGE EPROM and OTP EPROM	100nS	28P/DIP	12.75V	256K	3~5.5V	32K*8
18659	MX27C1000PC-12	MXIC	OTP EPROM 1Mb	1M	32P/PLCC	120ns	128K*8	12.5Vpp	5 V
1409	MX27C1000PC-70	MXIC	1M-BIT [128K x 8] CMOS EPROM	70ns	32P/DIP	12.5Vpp	1M	5V	128K*8
18660	MX27C1000QC-45	MXIC	OTP EPROM 1Mb	45ns	32P/PLCC	12.5Vpp	1M	5V	128K*8
1453	MX27C1000QC-90	MXIC	OTP EPROM 1Mb	90	32P/PLCC	12.5Vpp	1M	5	128K*8
18661	MX27C2000MC-12	MXIC	2M-BIT [256K x 8] CMOS EPROM	120ns	32P/SOP	12.5Vpp	2M	5 V	256K*8
1456	MX27C4000DC-15	MXIC	4M-BIT [512K x8] CMOS EPROM	150ns	32P/DIP	12.5Vpp	4M	5V	512K*8
1458	MX27C4100MC-12	MXIC	4M-BIT OTP CMOS EPROM	120nS	40P/SOP	12.5Vpp	4M	5V	512K*8
23621	TMS27C010A-12JL	T.I.	PROGRAMMABLE READ-ONLY MEMORIES	120ns	32P/DIP			5V	
22855	TMS27PC040-12FML	T.I.	PROGRAMMABLE READ-ONLY MEMORY	120nS	32P/SOP		4Mbit	5V	
22856	TMS27PC128-2NE	T.I.	PROGRAMMABLE READ-ONLY MEMORY		28P/DIP		16K * 8	5V	128K
1483	UPD27C1001AGW-15	NEC	EPROM 1M SMD	150ns	32P/PLCC	12.75Vpp	1M	5V	128K*8
39910	XC17128EPC	Xilinx	OTP PROM		20P-DIP				



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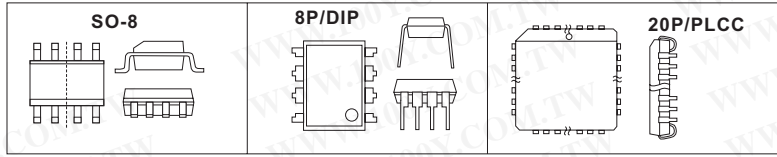
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## EEPROM记忆体 EEPROM

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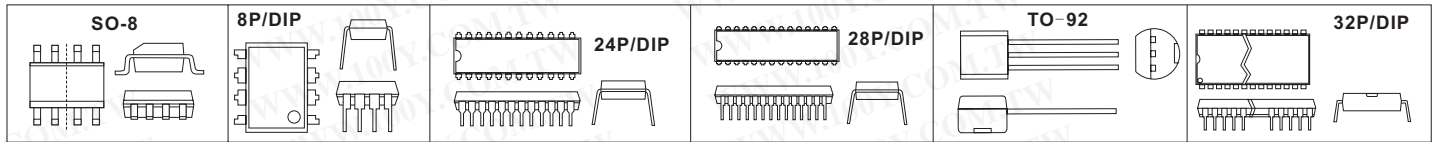
100Y 编号	厂商编号	制造厂商	说明	Size (bits*Word)	Organisation	Bus Configuration	Pin/Package	Volt.(Vcc)
18692	24AA64I/SN	MICRO-CHIP	64K I2C(TM) Serial EEPROM	64K	8K*8	2 wire serial	8P/SOIC	1.8V
1504	24L02B-I/P-e3	MICRO-CHIP	Serial EEPROM 【无铅】	2K	256*8	2 wire serial	8P/DIP	2.5-5.5V
40469	24LC00ISN	MICRO-CHIP	32K Serial EEPROM	32K	16K*8	2 wire	8p/soic	+2.5v to 5.5v
1489	24LC02B-I/P-e3	MICRO-CHIP	CMOS EEPROM SOP-8 SOP-8 256X8 SERIAL	2K	256*8	2 wire serial	8P/SOIC(150mil)	2.5V
17169	24LC02B/SN	MICRO-CHIP	Serial EEPROM	2K	256*8	2 wire serial	8P/SOIC(150mil)	2.5V
5376	24LC04B/P	MICRO-CHIP	4K Serial EEPROM	4K	512*8	2 wire serial	8P/DIP	2.5-5V
18693	24LC08B/SN	MICRO-CHIP	8K I2C TM Serial EEPROM	8K	4 x 256 x 8	2 wire serial	8P/SOIC	2.5-5.5V
40003	24LC128I/P	MICRO-CHIP	CMOS Serial EEPROM	128Kbit			DIP/8P	2.5-5.5V
1506	24LC16B/P	MICRO-CHIP	16K 2.5V Serial EEPROM	16K	2K*8	2 wire serial	8P/DIP	2.5V
46696	24LC16BI/P	MICRO-CHIP	EEPROM 记忆体	16K	2K*8	2 wire serial	8P/DIP	2K*8
13756	24LC16BT/SN-e3	MICRO-CHIP	16K EEPROM	16K	2K*8	2 wire serial	8P/SOIC	2.5-5V
23170	24LC16BTMI-SN-M2	MICRO-CHIP	Serial EEPROM			2-wire serial	8P/SOIC	7V
5377	24LC21/P	MICRO-CHIP	Dual Mode Serial EEPROM	1K	128*8	2 wire serial	8P/DIP	2.5V
17682	24LC256-I/P	MICRO-CHIP	EEPROM	256K	32K*8	2 wire serial	8P/DIP	7V
46258	24LC256-I/SNG	MICRO-CHIP	记忆体	256K	32K*8	2 wire serial	8P/DIP	7V
36297	24LC256I/SM	MICRO-CHIP	CMOS Serial EEPROM	256Kbit			8P/SOIC	2.5-5.5V
23174	24LC256T-I/SM	MICRO-CHIP	CMOS Serial EEPROM		256Kbit	2-wire serial	8P/SOIC	2.5-5.5V
48650	24LC32A-I/SN	MICRO-CHIP	2.5V,32K EEPROM/ narrow SOIC-8	8K*8bits		2 wire serial	narrowSOIC-8	2.5V
15275	24LC32A/P	MICRO-CHIP	EEPROM	32K	4K*8	2 wire serial	8P/DIP	7V
30257	24LC64I/P-e3	MICRO-CHIP	64K Serial EEPROM	64K	8K*8	2 wire serial	8P/DIP	7V
18695	24LC64I/SN-e3	MICRO-CHIP	64K Serial EEPROM	64K	8K*8	2 wire serial	8P/SOIC (150mil)	7V
48651	24LC65-I/SM	MICRO-CHIP	64K Serial EEPROM SOIC-8			2 wire serial	SOIC-8	2.5V to 6V
35693	24LC65/P	MICRO-CHIP	Smart Serial EEPROM		64K		8P/DIP	2.5V
39175	24LC65/SM	MICRO-CHIP	Smart Serial EEPROM		64K		SOP-8	2.5V
22442	AT17C512-10JC	ATMEL	FPGA Configuration EEPROM memory	1M-bits	512K	2-wire Bus	20P/PLCC	-0.5-7V
29557	AT17LV512-10JC	ATMEL	ATMEL_FPGA Configuration EEPROM Memory	512-Kbit			20P/PLCC	-0.5-7V
22447	AT17LV512-10PC	ATMEL	FPGA Configuration EEPROM Memory	512-Kbit		2-wire Bus	8P/DIP	-0.5-7V
13058	AT17LV65-10PC	ATMEL	FPGA Configuration EEPROM Memory	65K	524,288*1	2 wire serial	8P/DIP	7V
24785	AT24C01B-PU	ATMEL	2-Wire Serial EEPROM	1K	128*8	2-Wire Serial	DIP/8P	1.8-5.5V
18702	AT24C01BN-SH	ATMEL	2-Wire Serial EEPROM	1K	128*8	2-Wire Serial	8P/SOIC	1.8-5.5V
18703	AT24C02-10PI-2.7	ATMEL	2-wire Serial EEPROM	2K	256*8	2 wire serial	8P/DIP	2.7V
1503	AT24C02-10PU-1.8	ATMEL	2-wire Serial EEPROM	2K	256*8	2 wire serial	8P/DIP	1.8V
18704	AT24C02-10TI-2.7	ATMEL	2-wire Serial EEPROM	2K	256*8	2 wire serial	8P/TSSOP	2.7V
46276	AT24C02B-PU	ATMEL	记忆体	2K	256*8	2 wire serial	8P/DIP	1.8V
29241	AT24C02B-TH	ATMEL	EEPROM 记忆体 NiPdAu Lead Finish				8P/TSSOP	1.8V
41024	AT24C02BN-SH	ATMEL	2-wire Serial EEPROM 【无铅】	2K	256*8	2 wire serial	8P/SOIC	1.8-5.5V
18705	AT24C02N-10SI-2.7	ATMEL	2-wire Serial EEPROM	2K	256*8	2 wire serial	8P/SOIC	2.7V
40573	AT24C02N-10SU-2.7	ATMEL	2-wire Serial EEPROM	2K	256*8	2 wire serial	8P/SOIC	2.7V
23530	AT24C04-10PI	ATMEL	2-wire Serial EEPROM			2 wire serial	8P/DIP	1.8-5.5V
46273	AT24C04B-PU	ATMEL	记忆体	4K	512*8	2 wire serial	8P/DIP	1.8-5.5V
18707	AT24C04B-TH	ATMEL	2-wire Automotive Serial EEPROM	4K	512*8	2 wire serial	8P-TSSOP	1.8-5.5V
18711	AT24C04BN-SH	ATMEL	2-wire Automotive Serial EEPROM	4K	512*8	2 wire serial	8P/SOIC	1.8-5.5V
18714	AT24C04N-10SI-2.7	ATMEL	2-wire Automotive Serial EEPROM	4K	512*8	2 wire serial	8P/SOIC	2.7V
17616	AT24C08A-10PI-2.7	ATMEL	2-wire Serial EEPROM	8K	1K*8	2 wire serial	8P/DIP	2.7V
40889	AT24C08A-10PU-2.7	ATMEL	2-wire Serial EEPROM	8K	1K*8	2 wire serial	8P/DIP	2.7V
18715	AT24C08AN-10SU-2.7	ATMEL	2-wire Serial EEPROM	8K	1K*8	2 wire serial	8P/SOP	2.7V
16896	AT24C1024-10PI-2.7	ATMEL	2-wire Serial EEPROM	1M	128K*8	2 wire serial	8P/DIP	2.7V
16499	AT24C128N-10SI-2.7	ATMEL	2-wire Serial EEPROM	131,072	16,384 x 8	2-wire Serial	8P/SOIC	2.7V
39172	AT24C128N-10SU-2.7	ATMEL	2-wire Serial EEPROM 无铅	131,072	16,384 x 8	2-wire Serial	8P/SOIC	2.7V
17149	AT24C128PC	ATMEL	2-wire Serial EEPROMs	131,072	16,384 x 8	2-wire Serial	8P/DIP	2.7-5.5V
19610	AT24C128PI-2.7	ATMEL	2-wire Serial EEPROMs	131,072	16,384 x 8	2-wire Serial	8P/DIP	2.7V
18717	AT24C16A-10PI-2.7	ATMEL	2-wire Serial EEPROM	16K	2K*8	2 wire serial	8P/DIP	5V
40339	AT24C16A-10PU-2.7	ATMEL	2-wire Serial EEPROM	16K	2K*8	2 wire serial	8P/DIP	2.7-5V
18719	AT24C16A-10TU-1.8	ATMEL	16K(2K*8)EEPROM	16K	2K*8	2 wire serial	8P/TSSOP	1.8-5.5V
46274	AT24C16AN-10SU-1.8	ATMEL	记忆体 【无铅】	16K	2K*8	2 wire serial	8P/SOIC	1.8-5.5V
18718	AT24C16AN-10SU-2.7	ATMEL	2-wire Serial EEPROM 【无铅】	16K	2K*8	2 wire serial	8P/SOIC	2.7-5.5V
1508	AT24C16N-10SC-2.7	ATMEL	2.7V 16K(2K*8)EEPROM	16K	2K*8	2 wire serial	8P/SOIC	2.7-5.5V
15982	AT24C256-10PI-2.7	ATMEL	2-wire Serial EEPROM	256K	32K*8	2 wire serial	8P/DIP	2.7-5.5V
41023	AT24C256-10PU-2.7	ATMEL	2-wire Serial EEPROM	256K	32K*8	2 wire serial	8P/DIP	2.7-5.5V
16503	AT24C256N-10SI-2.7	ATMEL	2-wire Serial EEPROMs	256K	32,768 x 8	2-wire Serial	8P/SOIC	2.7V
38946	AT24C256N-10SU-2.7	ATMEL	2-wire Serial EEPROMs	256K	32,768 x 8	2-wire Serial	8P/SOIC	2.7V
1510	AT24C32A-10PU-1.8	ATMEL	2-Wire Serial EEPROM 32K (Lead-Free)	32K	4K*8	2 wire serial	8P/DIP	1.8-5V
46343	AT24C32A-10TU-2.7	ATMEL	2-Wire Serial EEPROM 32K (4096 x 8)	32K	4K*8	2 wire serial	TSSOP-8	2.7-5.5V





## EEPROM

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100Y 编号	厂商编号	制造厂商	说明	Size (bits*Word)	Organisation	Bus Configuration	Pin/Package	Volt.(Vcc)
18721	AT24C32AN-10SU-2.7	ATMEL	2-Wire Serial EEPROM 32K (4096 x 8)	32K	4K*8	2 wire serial	8P/SOIC 0.15" Wide	2.7-5.5V
44633	AT24C32CN-SH	ATMEL	2-WireSerial EEPROM-Lead Free	32K	4096*8	2-Wire	8-SOIC 0.15" Wide	1.8-3.6V
16985	AT24C512-10PU-2.7	ATMEL	2-wire serial EEPROM (Lead-Free)	512K	64K*8	2 wire serial	8P/DIP	2.7-5.5V
46334	AT24C512N-10SU-2.7	ATMEL	记忆体	65,536*8	512K	2 wire Serial	8P/SOIC	2.7-5.5V
15897	AT24C64A-10PI-2.7	ATMEL	2-Wire Serial EEPROM (工业用 Lead Free)	64K	8K*8	2 wire serial	8P/DIP	2.7-5V
1512	AT24C64A-10PU-1.8	ATMEL	2-Wire Serial EEPROM (Lead-Free)64K (8192 x 8)	64K	8K*8	2 wire serial	8P/DIP	1.8-5V
46333	AT24C64A-10PU-2.7	ATMEL	2-Wire Serial EEPROM 【无铅】	8192*8	64K	2 wire serial	DIP-8P	2.7-5V
18722	AT24C64AN-10SU-1.8	ATMEL	2-Wire Serial EEPROM-Lead Free	64K	8192*8	2 wire serial	8P/SOIC 0.15" Wide	1.8-5V
23532	AT24C64AN-10SU-2.7	ATMEL	2-Wire Serial EEPROM 【无铅】	8192*8	64K	2 wire serial	8P/SOIC	2.7-5V
32695	AT25010-10PC	ATMEL	SPI Serial EEPROM	1K	128 x 8		8P/PDIP	1.8V to 5.5V
22453	AT25020-10PC	ATMEL	SPI Serial EEPROM	256*8	2K	3-wire	8P/PDIP	2.7V-5.5V
17310	AT25040-10PI-2.7	ATMEL	SPI Serial EEPROMs	4K	512*8	3 wire serial	8P/DIP	5.5V
22456	AT25040N-10SI-2.7	ATMEL	SPI Serial EEPROM	512*8	4K	3-wire	8P/SOIC	2.7-5.5V
39632	AT25256AW-10SI-2.7	ATMEL	SPI Serial EEPROM	256K	32,768 x 8		8P/SOIC	2.7V to 5.5V
1490	AT28C16-15JC	ATMEL	16K (2K x 8) PCMCIA Nonvolatile Attribute Memory	16K	2K*8		32P/PLCC	5V
1514	AT28C16-15PC	ATMEL	16K (2K x 8) Parallel EEPROMs	16K	2K*8		24P/DIP	5V
18723	AT28C16E-15PC	ATMEL	16K (2K x 8) Parallel EEPROM	16K	2K*8		24P/DIP	5V
18724	AT28C256-15JU	ATMEL	256K (32K*8) Parallel EEPROM	256K	32K*8	3 wire serial	32P/PLCC	5V
1491	AT28C256-15PU	ATMEL	Atmel Parallel EEPROM	256K	32K*8	3 wire serial	28P/DIP	5V
49822	AT28C256E-20TI	ATMEL	256K (32K x 8)PagedCMOSE2PROM	256K	32K x 8		28P/TSSOP	
46463	AT28C256F-15PU	ATMEL	记忆体	256K	32K*8		28P/DIP	5
32705	AT28C64B-15PU	ATMEL	Parallel EEPROM	64K	8K*8		28P/PDIP	5V
18726	AT28C64E-12JC	ATMEL	64K(8Kx8)Parallel EEPROM with Page Write and Software Data Protection	64K	8K*8	2 wire serial	32P/PLCC	5V
49825	AT28HC64B-12JI	ATMEL	64K (8K x 8)High SpeedCMOSE2PROM withPage Write andSoftware DataProtection	64K	8K x 8		32P/PLCC	
18737	CAT24WC02J	CATALYST	2K Bit Serial EEPROM	2K	512*8		8P/SOIC	1.8V
42010	DS2430A	DALLAS	256-Bit 1-Wire EEPROM				TO-92	2.8V to 6.0V
41006	HD637B01YOP	HITACHI	CMOS Serial EEPROM		256Kbit		DIP/64P	+5V
18755	HT24LC02	HOLTEK	2K 2-Wire CMOS Serial EEPROM	2K	256*8	2 wire serial	8P/DIP	2.4-5.5V
49271	HT24LC16	HOLTEK	CMOS 16K 2-Wire Serial EEPROM	16K	2048*8	2 wire serial	SO-8	2.2-5.5V
22687	M24C01-WDW6T	ST(SGS)	Bus EEPROM	1K	128*8	2wire serial	8P/TSSOP	2.5-5.5V
34792	M24C02-WMN6T	ST(SGS)	I2C serial access EEPROM	256 x 8	2 Kbit		SO-8	2.5 to 5.5V
46335	M24C02-WMN6TP	ST(SGS)	记忆体	256 x 8	2 Kbit		SO-8	2.5 to 5.5V
22698	M28C64-20K6	ST(SGS)	PARALLEL EEPROM with SOFTWARE DATA PROTECTION	64K	8K*8		32P/PLCC	5V
22699	M28C64C-200K1	ST(SGS)	Parallel EEPROM	64K	8K*8		32P/PLCC	5V
34874	M93C86-WBN6	ST(SGS)	MICROWIRE Serial Access EEPROM	2048 x 8	16 Kbit		8P/DIP	2.5 to 5.5V
34877	M95128-WMN6	ST(SGS)	128Kbit Serial SPI Bus EEPROM With High Speed Clock	16384 x 8	128 Kbit		SO-8	2.5 to 5.5V
34881	M95640-WBN6	ST(SGS)	64Kbit Serial SPI Bus EEPROM With High Speed Clock	8192 x 8	64 Kbit		8P/DIP	2.5 to 5.5V
18757	NM24C08LM8X	NEC	8K-Bit Standard 2-Wire Bus Interface Serial EEPROM	8K		2 wire serial	8P/SOIC	2.4-5.5V
23603	SST29EE020-120-4C-NH	SST	Page-Mode EEPROM	256K*8	2 M		32P/PLCC	5.0V
22840	ST24LW21FB6	ST(SGS)	Dual Mode Serial EEPROM for VESA PLUG & PLAY	1Mbit	128*8	2 wire serial	8P/DIP	3.6-5.5V
39033	TC89102P	TOSHIBA	SERIAL E2PROM	2048	256*8	2 wire serial	8P/DIP	5V
23546	X24645	XICOR	Advanced 2-Wire Serial EEPROM with Block Lock Protection	8*8192	64Kbit	2-wire serial	8P-SOIC	2.7-5.5V
23151	X24C02S8-3T	XICOR	Serial EEPROM	2M	256 * 8 Bit	2 wire serial	8P/SOIC	2.7-5.5V
19109	X24C44P	XICOR	CMOS Serial NOVRAM	256BIT	16*16(256B)	Serial Port Compatible	8P/DIP	5V ±10%
47246	X25128PI	XICOR	EEPROM 记忆体	16K*8	128K		DIP-8	5.5V
18794	X2816CP-20	XICOR	5 Volt, Byte Alterable E2PROM	16K	2K*8		24P/DIP	5V
18809	X28C16J	EXEL	16K (2K x 8) PCMCIA Nonvolatile Attribute Memory	16K	2K*8		32P/PLCC	5V
33084	X28C256P	XICOR	5 Volt, Byte Alterable E2PROM	256K	32K x 8 Bit		28P/P DIP	5V
34423	X28C512D-15	XICOR	5 Volt, Byte Alterable EEPROM	512K	64K x 8		32P/DIP	5V
13196	X28C64P-20	XICOR	64K (8K x 8bit) 5 volt, byte alterable E2PROM	64K	8K*8	3 wire serial	28P/DIP	5V
36298	X28C64P-25	XICOR	64K (8K x 8bit) 5 volt, byte alterable E2PROM	64K	8K*8	3 wire serial	28P/DIP	5V



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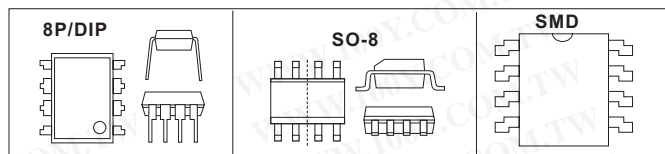
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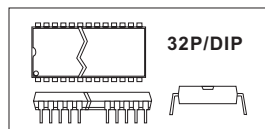
## 93系列EEPROM

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100Y 编号	厂商编号	制造厂商	说明	Organisation	Size (bits*Word)	Bus Configuration	Volt.(Vcc)	Pin/Package
22422	93LC46A/SN	MICRO-CHIP	1K Microwire Serial EEPROM	1024bits	128*8bits (64*16)	3 wire serial	6.5V	8P/SOIC
24671	93LC46B/P-e3	MICRO-CHIP	EEPROM	64 x 16 bit	1K	3-wire serial	7V	DIP/8P
18696	93LC46B/SN	MICRO-CHIP	1K 2.5V Microwire Serial EEPROM	128*8 or 64*16	1024	3 wire serial	2.5V	8P/SOIC
16420	93LC46BT/SN-e3	MICRO-CHIP	1K Microwire-Compatible Serial EEPROM	64*16	1K	3 wire serial	7V	8P/SOIC
18697	93LC46X/SN	MICRO-CHIP	1K 2.5V Microwire Serial EEPROM	128*8 or 64*16	1024	3 wire serial	2.5V	8P/SOIC
18698	93LC56B/P	MICRO-CHIP	2K 2.5V Microwire Serial EEPROM	256*8 or 128*16	2048	3 wire serial	2.5V	8P/DIP
19749	93LC56BT-SN	MICRO-CHIP	2K Microwire Compatible Serial EEPROM	128*16	2048	3 wire serial	7V	8P/SOIC
18699	93LC56N		2K 2.5V Microwire Serial EEPROM	256*8 or 128*16	2048	3 wire serial	2.5V	8P/DIP
3679	93LC66B/P-e3	MICRO-CHIP	Microchip 3-Wire Interface Serial EEPROMs 2.5V	512*8 or 256*16	4096	3 wire serial	2.5V	8P/DIP
18700	93LC66BT/SN-e3	MICRO-CHIP	Microchip 3-Wire Interface Serial EEPROMs 2.5V	512*8 or 256*16	4096	3 wire serial	2.5V	8P/SOIC
41025	93LC86-I/P-e3	MICRO-CHIP	16K 2.5V MicrowireR Serial EEPROM	1024 x 8 or 512 x 16	8192	3 wire serial	2.5V	8P/DIP
18701	93LC86/P-e3	MICRO-CHIP	16K 2.5V MicrowireR Serial EEPROM	1024 x 8 or 512 x 16	8192	3 wire serial	2.5V	8P/DIP
18727	AT93C46-10PI-2.7	ATMEL	3-wire Serial EEPROMs	128*8 or 64*16	1K	3-wire Serial	2.7-5V	8P/DIP
1522	AT93C46-10PU-1.8	ATMEL	3-wire Serial EEPROM Lead Free	64*16	1K	3-wire Serial	1.8-5V	8P/DIP
19256	AT93C46-10PU-2.7	ATMEL	3-wire Serial EEPROM	64*16	1K	3-wire Serial	2.7-5.5V	8P/DIP
1524	AT93C46-10SC-1.8	ATMEL	3-wire Serial EEPROM	64*16	1K	3-wire Serial	1.8-5.5V	8P/SOIC
1525	AT93C46-10SI-2.7	ATMEL	EEPROM 8P-SOP (I)	64*16	1K	3-wire Serial	2.7-5.5V	8P/SOIC
18728	AT93C46-10SU-2.7	ATMEL	3-wire Serial EEPROM	128*8 or 64*16	1K	3-wire Serial	2.7-5.5V	8P/SOIC
18730	AT93C46A-10SI-2.5	ATMEL	3-wire Serial EEPROM	128*8 or 64*16	1K	3-wire Serial	2.5-5V	8P/SOIC
1523	AT93C46D-PU	ATMEL	3-wire Serial EEPROM	64*16	1K	3-wire Serial	1.8-5.5V	8P/DIP
18729	AT93C46D-TH	ATMEL	3-wire Serial EEPROM	128*8 or 64*16	1K	3-wire Serial	1.8-5V	8P/TSSOP
18732	AT93C46DN-SH	ATMEL	3-wire Serial EEPROM	128*8 or 64*16	1K	3-wire Serial	1.8-5.5V	8P/SOIC
39635	AT93C46E-PU	ATMEL	3-wire Serial EEPROM	128*8 or 64*16	1K	3-wire Serial	1.8-5.5V	8P/DIP
18731	AT93C46EN-SH	ATMEL	3-wire Serial EEPROM	128*8 or 64*16	1K	3-wire Serial	1.8-5V	8P/SOIC
17170	AT93C56A-10PU-1.8	ATMEL	3-wire Serial EEPROM	128*16	2K	3-wire Serial	1.8-5.5V	8P/DIP
1499	AT93C56A-10PU-2.7	ATMEL	MICROWIRE Serial Access EEPROM	128*16	2K	3-wire Serial	2.7-5.5V	8P/DIP
18733	AT93C56A-10SU-1.8	ATMEL	3-wire Serial EEPROM	256*8 or 128*16	2K	3-wire Serial	1.8-5V	8P/SOIC
22515	AT93C56A-10TU-1.8	ATMEL	2K-bit Serial EEPROM memory devices		2K*8or16		1.8- 5.5V	8P/TSSOP
18734	AT93C66-10PC	ATMEL	3-wire Serial EEPROM	512 x 8 or 256 x 16	4K	3-wire Serial	4.5-5.5V	8P/DIP
1500	AT93C66-10PC-2.7	ATMEL	3-wire Serial EEPROM	256*16	4K	3-wire Serial	2.7-5.5V	8P/DIP
18735	AT93C66-10SC	ATMEL	3-wire Serial EEPROM	512 x 8 or 256 x 16	4K	3-wire Serial	4.5-5.5V	8P/SOIC
18736	AT93C66-10SI-2.7	ATMEL	3-wire Serial EEPROM	512 x 8 or 256 x 16	4K	3-wire Serial	2.7V	8P/SOIC
1527	AT93C66A-10PU-1.8	ATMEL	EEPROM	256*16	4K	3-wire Serial	1.8-5.5V	8P/DIP
22247	AT93C66A-10PU-2.7	ATMEL	3-wire Serial EEPROM	256*16	4K	3-wire Serial	2.7-5.5V	8P/DIP
1528	AT93C66A-10SU-1.8	ATMEL	3-wire Serial EEPROM	256*16	4K	3-wire Serial	1.8-5.5V	8P/SOP
19188	AT93C66A-10SU-2.7	ATMEL	3-wire Serial EEPROM	512 x 8 or 256 x 16	4K	3-wire Serial	2.7V	8P/SOIC
18738	AT93C66A-10TU-2.7	ATMEL	4K Bit Microwire Serial EEPROM		4K		2.7-5.5V	TSSOP
18739	AT93C66AW-10SU-1.8	ATMEL	4K Bit Microwire Serial EEPROM		4K		1.8-5.5V	0.2" Wide 8P/SOIC
14147	AT93C86-10SC-2.7	ATMEL	3-wire Serial EEPROM	2048*8 or 1024*16	16K	3 wire serial	2.7-5.5V	8P/SOIC
22516	AT93C86A-10PU-1.8	ATMEL	Microwire Serial EEPROM		16K(2048*8 or 1024*16)		1.8 -5.5V	8P/DIP
23543	AT93C86A-10SU-1.8	ATMEL	3-wire Serial EEPROM	2048 *8 or 1024 *16	16K	3-wire Serial	1.8-5.5V	8P/SOIC
41304	AT93C86A-10SU-2.7	ATMEL	3-wire Serial EEPROM	2048 *8 or 1024 *16	16K	3-wire Serial	2.7-5.5V	8P/SOIC
22514	CAT93C46P	CATALYST	Microwire Serial EEPROM		1K*8or16		1.8-6.0V	8P/DIP
27929	HT93LC46-B	HOLTEK	EEPROM	64*16	1K	Serial I/O	3-5V	8P/SOP
18756	KM93C46GD	SAMSUNG	1024-bits serial electrically erasable PROM		1024		5V	8P/SOP
1538	M9306B	ST(SGS)	EEPROM (同 NM9306N) SGS-Thomson	16*16	256K	Serial I/O	5V	8P/DIP
22703	M93C46-MN6	ST(SGS)	Serial Microwire Bus EEPROM	1K*8or16	1K		4.5-5.5V	8P/SOP
22774	NM93C06M8	N.S	Serial EEPROM		256Bits		4.5-5.5V	8P/SOP
18759	S93CC46BD-J8T1	SII(SEIKO)	1K-bit serial EEPROM	64*16	1K			8P/SOP
18807	XL93LC56JR		2K 2.5V Microwire Serial EEPROM	256*8 or 128*16	2048	3 wire serial	2.5V	SMD
1544	XL93LC66F	EXEL	EEPROM	256*16	4K	3 wire serial	5V	8P/SOP
18808	XL93LC66Y	EXEL	Microchip 3-Wire Interface Serial EEPROMs 2.5V	512*8 or 256*16	4096	3 wire serial	2.5V	8P/SOIC

## 静态式记忆体 SRAM



100Y 编号	厂商编号	制造厂商	说明	Pin/Package	Size	Organisation	Access Time
49319	AS7C1025-12JC	Alliance	5V/3.3V 128K*8 CMOS SRAM	SOJ-32P		128K*8	12ns
49320	AS7C1025-15JC	Alliance	5V/3.3V 128K*8 CMOS SRAM	SOJ-32P	15ns	128K*8	
36447	BQ4013YMA-120	T.I.	128Kx8 Nonvolatile SRAM	32P/DIP		128Kx8	120ns
46247	BS62LV1027PCG-70	BSI	静态式记忆体	DIP-32	1024K	128K*8	70NS
46248	BS62LV1027PCP-70	BSI	静态式记忆体	DIP-32	1024K	128K*8	70NS
46255	BS62LV4006PCP-70	BSI	静态式记忆体	DIP-32	1024K	128K*8	70NS

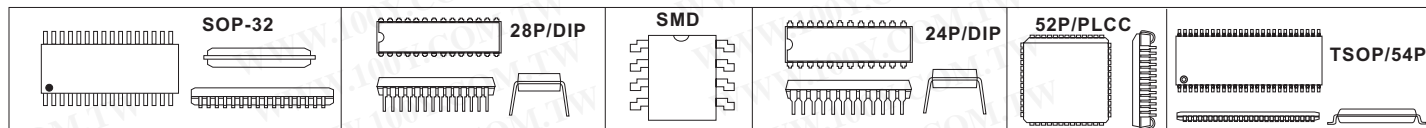
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# 记忆IC

## SRAM

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100Y 编号	厂商编号	制造厂商	说明	Pin/Package	Size	Organisation	Access Time
19030	BS62LV1024SC-70	BSI	VERY LOW POWER/VOLTAGE CMOS SRAM	32P/SOP	1M	128K*8	70ns
46251	BS62LV1027SCG-70	BSI	静态式记忆体	SOP-32	1024K	128K*8	70NS
46252	BS62LV1027SCP-70	BSI	静态式记忆体	SOP-32	1024K	128K*8	70NS
46253	BS62LV1027SIG-70	BSI	静态式记忆体	SOP-32P	1024K	128K*8	70NS
46254	BS62LV1027SIP-55	BSI	静态式记忆体	SOP-32	1024K	128K*8	55NS
19032	BS62LV2001SC-70	BSI	Very Low Power/Voltage CMOS SRAM	32P/SOP		256K*8	70ns
19034	BS62LV256PC-70	BSI	Very Low Power/Voltage CMOS SRAM	28P/PDIP		32K*8	70ns
46241	BS62LV256PC-70	BSI	静态式记忆体	DIP		32K*8	70ns
46242	BS62LV256PIP-70	BSI	静态式记忆体	28P/PDIP		32K*8	70
19035	BS62LV256SC-70	BSI	Very Low Power/Voltage CMOS SRAM	28P/SOP		32K*8	70ns
46243	BS62LV256SCP-70	BSI	静态式记忆体	28P/SOP		32K*8	70
14092	BS62LV256TC-70	BSI	VERY LOW POWER/VOLTAGE CMOS SRAM	28P/TSOP	256K	32K*8	70ns
46256	BS62LV4006SCP-55	BSI	静态式记忆体	SOP-32	1024K	128K*8	55NS
1581	CXK581000AM-70SL	SONY	131072-word x 8-bit High Speed CMOS Static RAM	32P/SOP	1M	131072*8	70ns
19036	CXK581000ATM-10LL	SONY	256K-SRAM	32P/TSOP	256K	32768*8	100ns
19037	CXK581000ATM-10SL	SONY	256K-SRAM SUPER LOW POWER	32P/TSOP	256K	32768*8	100ns
19038	CXK581000ATM-70LL	SONY	256K-SRAM SUPER LOW POWER	32P/TSOP	256K	32768*8	70ns
19039	CXK581001M-70L	SONY	SRAM	SMD	1M		70ns
1583	CXK5816M-15L	SONY	16K-SRAM	24P/SOP	16K	2048*8	150nS
19040	CXK5816MA-15L	SONY	SRAM	24P-SMD	16K	2K*8	150ns
48499	CXK58256PF-12L	SONY	32K WORD X 8 BIT HIGH SPEED CMOS STATIC RAM	28P/DIP	32K*8bit	32768*8	120ns
48549	CXK58257AP-10L	SONY	SRAM	28P/DIP	256K	32768*8	10ns
1589	CXK58257ASP-120ns	SONY	256K-SRAM	28P/DIP-300mil	256K	32768*8	120ns
19041	CXK58257ATM-10L	SONY	256K-SRAM	28P/TSOP	256K	32768*8	100ns
19042	CXK58257ATM-10LL	SONY	256K-SRAM	28P/TSOP	256K	32768*8	100ns
19043	CXK58257ATM-10LLX	SONY	256K-SRAM	28P/TSOP	256K	32768*8	100ns
19044	CXK58257ATM-10LX	SONY	256K-SRAM	28P/TSOP	256K	32768*8	100ns
1586	CXK58257ATM-12LL	SONY	256K-SRAM	28P/SOIC	256K	32768*8	120ns
19045	CXK58257BM-10LL	SONY	SRAM	SMD	256K	32768*8	100ns
23544	CXK58257CM-70LL	SONY	High Speed CMOS Static RAM	28P/SOIC	32768word*8bit		70ns
19046	CXK584000YM-70LL	SONY	SRAM	TSOP	4M		
1590	CXK5864CP-10LL	SONY	64K-SRAM	24P/DIP	64K	8192*8	100ns
19047	CXK5T81000ATM-10LLX	SONY	SRAM	TSOP			100ns
19048	CXK5T8257BM-12LLX	SONY	SRAM	SMD			120ns
19049	CXK5V81000ATM-10LLX	SONY	SRAM	TSOP			100ns
19050	CXK5V8257BM-70LL	SONY	SRAM	SMD			70ns
19051	CY62128BLL-70SC	Cypress	128K x 8 Static RAM	32P/SOIC		128K*8	70ns
23547	CY62128L-70SC	Cypress	Static RAM	32P/SOIC	128K *8		70 ns
32933	CY62256LL-70PC	Cypress	32Kx8 Static RAM	28P/DIP	32K	32K*8	70ns
19052	CY62256LL-70SNC	Cypress	32Kx8 Static RAM	28P/SOIC		32K*8	70ns
17362	CY7C128A-35DMB	Cypress	Static RAM	24P/DIP	2K*8	16K	35ns
22331	CY7C136-55JC	Cypress	Dual-Port Static RAM	52P/PLCC	16K	2Kx8	55
23262	CY7C150-35DMB	Cypress	1K*4 Static RAM	24P/DIP	1K*4		35ns
17363	CY7C185A-35DMB	Cypress	Static RAM	28P/DIP	8K x 8	64K	35ns
22574	CY7C199-15VCT	Cypress	32K x 8 Static RAM	28P/SOJ	32K x 8		15nS
23261	CY7C245A-35DMB	Cypress	Reprogrammable Registered PROM	24P/DIP	16K	2K*8	35ns
23648	CY7C245A-35WC	Cypress	Reprogrammable Registered PROM	24P/ Windowed DIP	16K	2K*8	35ns
17364	CY7C263-45DMB	Cypress	8K x 8 Power-Switched and Reprogrammable PROM	24P/DIP	8K x 8	64K	45ns
16404	D431000ACZ-70L	NEC	1M-BIT CMOS STATIC RAM	32P/DIP	1M	128*8bit	70ns
33003	DS1216B	DALLAS	SmartWatch RAM	28P/DIP	16k/64k	512k x 8	
33004	DS1216C	DALLAS	SmartWatch RAM	28P/DIP	64k/256k	512k x 8	
41906	DS1553WP-120	MAXIM	64kB, Nonvolatile, Year-2000-Compliant Timekeeping RAM	34 PowerCap*			
41907	DS1556W-120	MAXIM	1M, Nonvolatile, Y2K-Compliant Timekeeping RAM	32 EMOD			
41908	DS1556WP-120	ALTEIRA	1M, Nonvolatile, Y2K-Compliant Timekeeping RAM	34 PowerCap*			
44899	DS1687-5	DALLAS	24 EDIP (0.740")/5V	EDIP-24			
41913	DS1688	MAXIM	3 Volt/5 Volt Serialized Real Time Clock with NV RAM Control	28P-DIP			
42022	DS3050W-100	DALLAS	3.3V Single-Piece 4Mb Nonvolatile SRAM with Clock	256-ball BGA Module		27mm x 27mm	
23561	EM638165-6	Etron	SRAM	TSOP/54P	4Meg*16	4K	60ns
19053	GM76C256CLLFW-55	HYNIX	SRAM	SMD			55ns
19055	GM76C8128CLLF-85	HYNIX	SRAM	SMD	1M		85ns
19054	GM76C8128CLLFW-70	HYNIX	SRAM	SMD	1M		70ns
19056	GM76FC18ALLFW-70	HYNIX	SRAM	SMD	1M		
19025	GM76V8128CLFW-70	HYNIX	SRAM	SMD	1M		70ns
19026	GM76V8128CLLFW-70	HYNIX	SRAM	SMD	1M		



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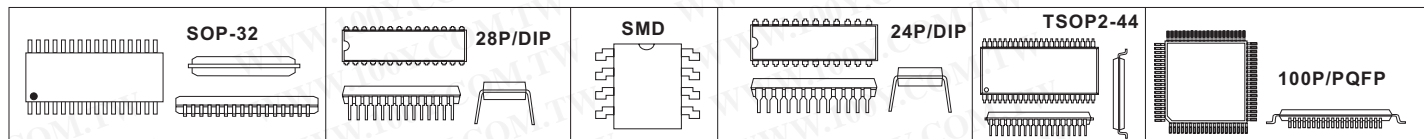
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# 记忆IC

## SRAM

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100Y 编号	厂商编号	制造厂商	说明	Pin/Package	Size	Organisation	Access Time
1597	HM6116LM-70	HMC	SRAM 16K	24P/SOP	16K	2K*8	70ns
19028	HM6116P-70L	HITACHI	SRAM	DIP			
19057	HM6264LM-70	HMC	SRAM	SMD	8K*8	8192*8	70ns
40196	HM6264LP-15	HMC	8192-WORD X 8-BIT HIGH SPEED CMOS STATIC RAM	28P/DIP	8K*8	8192*8	150NS
17171	HM6264LP-70	HMC	SRAM	28P/DIP	8K*8	8192*8	70ns
19058	HM6264WM-70L	HMC	SRAM	28P/SOP	8K*8	8192*8	70ns
19059	HM628128DLFP-55SL	HITACHI	1 M SRAM (128-kword*8-bit)	32P/SOP	1M	128K*8	55ns
33595	HM628511HJP-15	HITACHI	4M High Speed SRAM (512-kword x 8-bit)	36-pin plastic SOJ	4M	512-kword x 8-bit	15 ns
35487	HM628512CLFP-5	HITACHI	4 M SRAM	32P/SOP	4M	512K*8	55 ns
19060	HM628512CLFP-5SL	HITACHI	4M-SRAM	32P/SOIC			
33596	HM628512CLP-5SL	HITACHI	4 M SRAM (512-kword x 8-bit)	32-pin plastic DIP	4 M	512-kword x 8-bit	55 ns
4488	HM62V8128BLT-12	HITACHI	SRAM	32P/TSOP	1M	128K*8	120ns
19062	HY628100BLLG-70		128K x8 bit 5.0V Low Power CMOS slow SRAM	32P/SOP		128K*8	70ns
44806	IC61C256AH-12N	ISSI	静态式记忆体	28P/DIP	32K * 8	256K	12ns
23263	IDT6116SA45TDB	IDT	CMOS Static RAM	24P/DIP	2K*8bit	16K	45ns
23646	IS61C1024-12J	ISSI	HIGH-SPEED CMOS STATIC RAM	32P-SOJ	128K * 8	131072Word	12ns
23551	IS61C1024-15T	ISSI	HIGH-SPEED CMOS STATIC RAM	32P/TSOP	128K * 8	131072Word	15ns
23552	IS61C256AH-15J	ISSI	HIGH-SPEED CMOS STATIC RAM	28P/SOIC	32K * 8	256K	15ns
22626	IS61C256AH-20T	ISSI	HIGH-SPEED CMOS STATIC RAM	28P/TSOP	32K * 8		20ns
22627	IS61C512-15N	ISSI	HIGH-SPEED CMOS STATIC RAM	32P/DIP	64K*8		15, 20, 25, 35 ns
23553	IS61C64AH-20N	ISSI	HIGH-SPEED CMOS STATIC RAM	28P/SOIC	8K*8	64K	20ns
22631	IS61S6432-5PQ	ISSI	SYNCHRONOUS PIPELINE STATIC RAM	100P/PQFP	64K x 32		4nS
19063	IS62C1024-70Q	ISSI	128K x 8 HIGH-SPEED CMOS STATIC RAM	32P/TSOP	1M	128K*8	70ns
40556	IS62C1024-70T	ISSI	128K x 8 HIGH-SPEED CMOS STATIC RAM	32P/TSOP	1M	128K*8	70ns
39216	IS62C256-70U	ISSI	32K x 8 LOW POWER CMOS STATIC RAM	28P/SOP		32K x 8	70ns
22633	IS62LV1024LL-55H	ISSI	LOW POWER and LOW Vcc CMOS STATIC RAM	32P/TSOP	128K*8		45,55,70ns
22634	IS62LV1024LL-70T	ISSI	LOW POWER and LOW Vcc CMOS STATIC RAM	32P/TSOP	128K*8		45,55,70ns
41617	IS63LV1024-10T	ISSI	HIGH-SPEED CMOS STATIC RAM	32P/TSOP	128K x 8		8, 10, 12 and 15 ns
22635	IS63LV1024-12J	ISSI	HIGH-SPEED CMOS STATIC RAM	32P/SOJ	128K x 8		10, 12 and 15 ns
41619	IS63LV1024-12K	ISSI	HIGH-SPEED CMOS STATIC RAM	400-mil Plastic SOJ	128K x 8		8, 10, 12 and 15 ns
41618	IS63LV1024-12T	ISSI	HIGH-SPEED CMOS STATIC RAM	TSOP	128K x 8		8, 10, 12 and 15 ns
42720	IS63LV1024-8J	ISSI	HIGH-SPEED CMOS STATIC RAM	SOJ	128K x 8		8ns
27819	K4S561632E-TL75	SAMSUNG	256Mb E-die SDRAM Specification	54P/TSOP	256M	16M*16	
46457	K6R4008V1D-UI10	SAMSUNG	静态式记忆体	TSOP2-44	2M	512K*8	10ns
19064	K6T1008C2C-DB55	SAMSUNG	128K x8 bit Low Power CMOS Static RAM	32P/DIP	1M	128K*8	55ns
19065	K6T1008C2C-GB55	SAMSUNG	128K x8 bit Low Power CMOS Static RAM	32P/SOP	1M	128K*8	55ns
34479	K6T1008C2E-DB55	SAMSUNG	128Kx8 bit Low Power CMOS Static RAM	32-DIP		128Kx8	55ns
34480	K6T1008C2E-DB70	SAMSUNG	128Kx8 bit Low Power CMOS Static RAM	32-DIP		128Kx8	70ns
19067	K6T1008C2E-GB70	SAMSUNG	128K x8 bit Low Power CMOS Static RAM	32P/SOP	1M	128K*8	70ns
23554	K6T1008C2E-GF70	SAMSUNG	Low Power CMOS Static RAM	32P/SOIC	128K*8bit		70ns
23555	K6T1008C2E-TB70	SAMSUNG	Low Power CMOS Static RAM	32P/TSOP	128K*8bit		70ns
19068	K6T4008C1B-GB55	SAMSUNG	512K x 8 bit Low Power CMOS Static RAM	32P/SOP	4M	512K*8	55ns
23556	K6T4008C1B-GP70	SAMSUNG	Low Power CMOS Static RAM	32P/SOIC	512K*8bit		70ns
19069	K6T4008C1C-GB55	SAMSUNG	512K x 8 bit Low Power CMOS Static RAM	32P/SOP	4M	512K*8	55ns
46411	K6X1008C2D-BF55	SAMSUNG	静态式记忆体	32P/SOP	128K*8		55ns
33163	K6X1008C2D-DF55	SAMSUNG	Low Power full CMOS Static RAM	32P/DIP	128K*8		55ns
23564	K6X1008C2D-DF70	SAMSUNG	Low Power full CMOS Static RAM	32P/DIP	128K*8		70ns
23565	K6X1008C2D-GB70	SAMSUNG	Low Power full CMOS Static RAM	32P/SOIC	128K*8		70ns
32111	K6X1008C2D-GF55	SAMSUNG	Low Power full CMOS Static RAM	32P/SOP	128K*8		55ns
46412	K6X1008C2D-PF70	SAMSUNG	静态式记忆体	TSOP-32	128K*8		70ns
23566	K6X1008C2D-TB70	SAMSUNG	Low Power full CMOS Static RAM	32P/TSOP	128K*8		70ns
46413	K6X4008C1F-BF55	SAMSUNG	静态式记忆体	SOP-32	4M	512K*8	55ns
46415	K6X4008C1F-BF70	SAMSUNG	静态式记忆体	32P/SOP	4M	512K*8	70ns
26222	K6X4008C1F-DF55	SAMSUNG	512K x 8 bit Low Power CMOS Static RAM	32P/DIP	4M	512K*8	70ns
23567	K6X4008C1F-GB55T	SAMSUNG	Low Power full CMOS Static RAM	32P/SOIC	512K*8bit		55ns
25935	K6X4008C1F-GB70	SAMSUNG	512K x 8 bit Low Power CMOS Static RAM	32P/SOP	4M	512K*8	70ns
19070	KM62256CLGE-10L	SAMSUNG	32Kx8 bit Low Power CMOS Static RAM	28-SOP	256K	32Kx8	100ns
37441	KM62256CLP-7L	SAMSUNG	32Kx8 bit Low Power CMOS Static RAM	28P/DIP	256K	32Kx8	70ns
19071	KM681000BLG-7L	SAMSUNG	128K*8 bit Low Power CMOS Static RAM	SMD	1M	128K*8	32P/SOP



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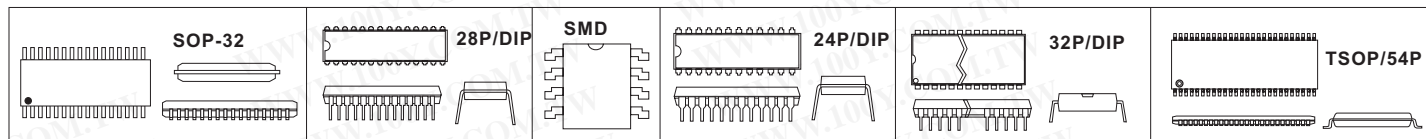
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## SRAM

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100Y 编号	厂商编号	制造厂商	说明	Pin/Package	Size	Organisation	Access Time
36444	KM684000BLP-7L	SAMSUNG	512Kx8 bit Low Power CMOS Static RAM	32P/DIP		512Kx8	70ns
19066	L6T1008C2E-GB55	SAMSUNG	128K x8 bit Low Power CMOS Static RAM	32P/SOP	1M	128K*8	55ns
19072	LC3564B-70	SANYO	64K SRAM	28P/DIP(600mil)	64K	8192word*8b	70ns
19073	LC361000AMLL-70	SANYO	1 MEG (131072 words x 8 bits) SRAM	32P/SOP	1M	131072*8	70ns
1604	LH5164L-10	SHARP	SRAM	28P/DIP	64K	8K*8	100ns
19074	LH52B256D-10PLL	MOSEL-VIT.	SRAM	DIP			100ns
27935	LP621024DM-70LL	AMIC	SRAM	SOP-32P	128K*8		
19076	LST62832I-70LL	LINK-SMART	SRAM	28P/DIP			70ns
28702	M48T02-150PC1	ST(SGS)	16K-SRAM	24P/DIP	16K		150nS
37344	M48T02-200PC1	ST(SGS)	16 Kbit (2Kb x8) TIMEKEEPER[ SRAM	24P/DIP	16K	200nS	2K*8
34855	M48T02-70PC1	ST(SGS)	16K-SRAM	24P/DIP	16K	2K*8	70ns
34857	M48T08-100PC1	ST(SGS)	64 Kbit (8Kb x 8) TIMEKEEPER SRAM	28P/DIP	64 Kbit	8Kb x 8	100ns
28947	M48T18-100PC1	ST(SGS)	静态式记忆体	28P/DIP	64 Kbit		
34860	M48T35-70PC1	ST(SGS)	256 Kbit (32Kb x8) TIMEKEEPER SRAM	28P/DIP	256 Kbit	32Kb x8	70ns
34862	M48Z02-200PC1	ST(SGS)	5V, 16 Kbit (2Kb x 8) ZEROPOWER SRAM	24P/DIP	16 Kbit	2Kb x 8	200ns
34865	M48Z08-100PC1	ST(SGS)	64 Kbit (8Kb x 8) ZEROPOWER SRAM	28P/DIP	64 Kbit	8Kb x 8	100ns
22759	M5M51008AVP-10VLL	MITSUBISHI	SRAM	TSOP	1M	128Kx8	70nS
19078	M5M51008BFP-10VLL	MITSUBISHI	SRAM,3.3V	TSOP	1M		
19077	M5M51008BP-70LL	MITSUBISHI	SRAM	32P/SOIC	1M		70ns
19079	M5M51008CFP-70H	MITSUBISHI	SRAM	32P/SOIC	1M		70ns
19080	M5M51008CFP-70HI	MITSUBISHI	SRAM	32P/SOP	1M		
19081	M5M51008CP-70H	MITSUBISHI	SRAM	32P/DIP	1M		
19082	M5M51008DVP-70H	MITSUBISHI	SRAM	TSOP	1M		70ns
19083	M5M51008FP-70L	MITSUBISHI	SRAM	32P/SOIC			70ns
19084	M5M5255DFP-70LL	MITSUBISHI	SRAM	28P/SOIC			70ns
1608	M5M5256CP-70LL	MITSUBISHI	SRAM	28P/DIP	256K	32K*8	70ns
19085	M5M5256DFP-10L	MITSUBISHI	SRAM	28P/SOIC			100ns
19090	M5M5256DFP-70LL	MITSUBISHI	SRAM	28P/SOIC			70ns
19091	M5M5256DVP-45LL	MITSUBISHI	SRAM	28P/TSOP			45ns
19092	MB84256C-70LLPFTN	FUJITSU	SRAM	TSOP			70ns
49536	MK48T02B-20	ST(SGS)	ST_CMOS 2K*8 TIMEKEEPER SRAM	DIP-24P		2K*8	200 ns
19097	MS6264CL-15FC	FUJITSU	SRAM	SOP			150ns
19098	MSM51257ALL-85RS	OKI Semi	SRAM	DIP			85ns
35488	MSM518221-30ZS	OKI Semi	2-Mbit, 256K*8-bit, Field Memory	28-pin ZIP	2M	256K*8	25 ns
40124	MSM51V8221A-30JS	OKI Semi	262,214-Word x 8-Bit Field Memory	400mil 28P/SOJ	2M	256K*8	30ns
23368	MT48LC4M16A2P-6	Micro-semi	64Mb SDRAM	54P/TSOP	64M	1Meg*16*4banks	6ns
35497	MT48LC4M16A2TG-75	Micro-semi	64Mb SDRAM	54P/TSOP	64M	1Meg*16*4banks	7.5ns
48504	P51256SL-07	INTEL	32K x 8 CMOS SLOW STATIC RAM	28P/DIP	256K	32K x 8	
40192	SRM2264LC		HIGH SPEED CMOS 64K-BIT STATIC RAM	28P/DIP			
1622	SRM2A256LC-70		SRAM	28P-DIP	256K	32K*8	85ns
19100	TC551001AFL-10LL	TOSHIBA	SRAM	SMD	1M		100ns
19101	TC551001BFL-70	TOSHIBA	SRAM	SMD			70ns
19102	TC55257DFL-70L	TOSHIBA	SRAM	SMD			70ns
19086	TMM2016BP-12		SRAM	DIP			120ns
19087	UM6116M-3L	UMC	SRAM	SMD			90ns
19088	UPD431000AGW-70LL	NEC	1M-BIT CMOS STATIC RAM	32P/SOP	1M	128K*8	70ns
19089	UPD431000AGZ-70LL-KJH	NEC	1M-SRAM	32P/TSOP	1M	131072*8Bits	70ns
1569	UPD43256BCZ-70LL	NEC	256K-BIT CMOS STATIC RAM 32K-WORD BY 8-BIT	28P/DIP	256K	32768*8	70ns
4090	UT621024PC-70LL	UTRON	SRAM	32P/SOP	1M	128K*8	70ns
19103	UT621024SC-70L	UTRON	128K X 8 BIT LOW POWER CMOS SRAM	32P/SOP	1M	128K*8	70ns
23622	UT62256CPC-70LL	UTRON	LOW POWER CMOS SRAM	28P/DIP	32K * 8		70ns
23623	UT62256CSC-70LL	UTRON	LOW POWER CMOS SRAM	28P/SOIC	32K*8	256K	70ns
22192	UT62256SC-70LL	UTC	32 K x 8 Bit low power CMOS SRAM	SOP-28 300mil	256K	32768*8	70ns
23145	V62C518256LL-70F	MOSEL-VIT.	STATIC RAM	28P/SOIC	32K * 8	256K	70ns
19104	V62C51864L-35P	MOSEL-VIT.	SRAM	28P/DIP			35ns
19105	V62C51864L-70P	MOSEL-VIT.	SRAM	28P/DIP			70ns
27907	W24257AJ-12		静态式记忆体	8P/SOJ	32K* 8	256K	12nS
23147	W24257AJ-15	WINBOND	HIGH SPEED CMOS STATIC RAM	8P/SOJ_300mil	32K* 8	256K	15nS
23148	W24257AK-15	WINBOND	HIGH SPEED CMOS STATIC RAM	28P/DIP	32K* 8	256K	15nS
19107	W24257S-100L	WINBOND	32K x 8 CMOS STATIC RAM	28P/SOP		32K*8	100ns
19106	W24257S-70L	WINBOND	32K x 8 CMOS STATIC RAM	28P/SOP		32K*8	70ns
14258	W24257S-70LL	WINBOND	32Kx8 CMOS STATIC RAM	28/SOP	256K	32768*8Bits	70ns
5379	W24258-70LL	WINBOND	32*8 normal speed, very low power CMOS static RAM	28P/DIP	256K	32768*8Bits	70ns
19108	W24258S-70LE	WINBOND	32K*8 CMOS STATIC RAM	28P/SOP		32K*8	70ns



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# 记忆IC

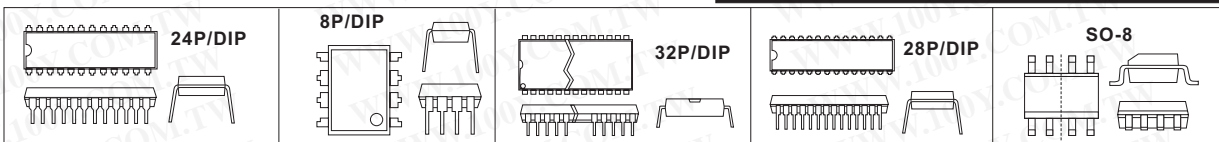
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100Y 编号	厂商编号	制造厂商	说明	Pin/Package	Size	Organisation	Access Time
15752	W24258S-70LL	WINBOND	32*8 normal speed, very low power CMOS static RAM	28P/SOP	32K* 8	32768*8Bits	70ns
1548	W2465S-70LL	WINBOND	8K x 8 CMOS STATIC RAM	28P/SOP	64K	8K*8	70ns
40621	W2465SG-7066	WINBOND	8K x 8 CMOS STATIC RAM	28P/SOP	64K	8K*8	70ns
15500	W24L11Q-70LE	WINBOND	128K x 8 CMOS STATIC RAM	32P/TSOP	128K*8	131072 x 8	70ns
40692	W24L257AJ-12	WINBOND	HIGH-SPEED CMOS STATIC RAM	28P/SOJ	32K* 8	256K	12nS
23149	W24L257AJ-15	WINBOND	HIGH-SPEED CMOS STATIC RAM	28P/SOJ	32K* 8	256K	15nS

## Nonvolatile SRAM

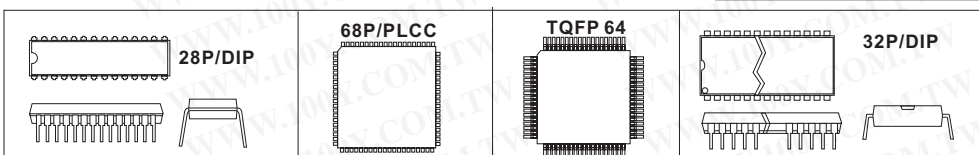
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100Y 编号	厂商编号	制造厂商	说明	Access Time	Pin/Package	Size
16257	DS1210	DALLAS	Nonvolatile Controller Chip	20ns	8P/DIP	
28512	DS1213C	DALLAS	SmalSocket for standard 32k*8 CMOS Static RAM		28P/DIP	32k*8
33007	DS1220AB-150	DALLAS	Nonvolatile SRAM 2K*8	150ns	24P/DIP	16K
29723	DS1220Y-120	DALLAS	Nonvolatile SRAM 2K*8	120ns	24P/DIP	16K
4845	DS1220Y-150	DALLAS	Nonvolatile SRAM 2K*8	150ns	24P/DIP	16K
45679	DS1220Y-200	DALLAS	DALLAS_Nonvolatile SRAM 2K*8	200ns	DIP-24P	16K
4481	DS1225Y-150	DALLAS	64K nonvol. SRAM 10% pwr 4.37V WP	150ns	28P/DIP	64K
31729	DS1225Y-200	DALLAS	64K nonvol. SRAM	200ns	DIP-28P	64K
4479	DS1230Y-100	DALLAS	256K nonvol.SRAM 10% pwr, 4.37V WP	100ns	28P/DIP	256K
33005	DS1230Y-120	DALLAS	256K Nonvolatile SRAM	120ns	28P/DIP	256K
33006	DS1230Y-70	DALLAS	256K Nonvolatile SRAM	70ns	28P/DIP	256K
39600	DS1243Y	DALLAS	64K NV SRAM with Phantom Clock	500ns	28P/DIP	64K
38141	DS1243Y-120	DALLAS	64K NV SRAM with Phantom Clock	120ns	28P/DIP	64K
17126	DS1245Y-70	DALLAS	Nonvolatile SRAM(1024 Novolatile sram)	70ns	32P/DIP	1024K
16564	DS1249Y-70	DALLAS	Nonvolatile SRAM(2048 Novolatile sram)	70ns	32P/DIP	2048K
19320	DS1302+	DALLAS	Trickle Charge Timekeeping Chip		8P/DIP	
19321	DS1302S	DALLAS	Trickle Charge Timekeeping Chip		8P/SOIC	
20244	X24C44S	XICOR	CMOS Serial NOVRAM	256BIT	16*16(256B)	Serial Port Compatible
43352	X24C44ST1	XICOR	CMOS Serial NOVRAM		8P/SOIC	256BIT

## 先进先出型-记忆体

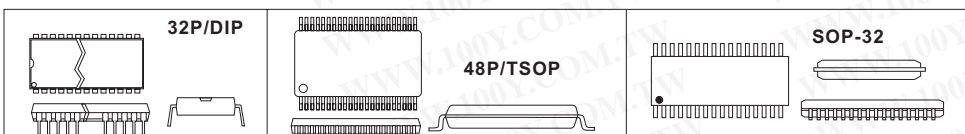
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100Y 编号	厂商编号	制造厂商	说明	Pins/Package	Organisation	Access Time
20112	CY7C429-20PC	Cypress	Asynchronous FIFO(2K x 9 asynchronous FIFO, 30 ns)	28P/DIP	2K*9	20ns
16449	CY7C429-30PC	Cypress	Asynchronous FIFO(2K x 9 asynchronous FIFO, 30 ns)	28P/DIP	2K*9	40ns
17480	IDT7210L45J	IDT	Multipliers and Dividers	68P-PLCC	16 x 16 Bit	45ns
21983	IDT72245LB10PF		CMOS SyncFIFO	TQFP 64	4096 x 18-bit Synchronous FIFO	10ns
39358	IDTQS4A101Q	IDT	QUICKSWITCH® PRODUCTSHIGH-PERFORMANCE CMOS ANALOGFOUR-CHANNEL SPST SWITCHWITH INDIVIDUAL ENABLES	Quarter Size Outline Package		6.5ns
13205	SN74ACT72241L50RJ	T.I.	synchronous FIFO	32P/PLCC	4K*9	15ns

## 快闪式记忆体

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100Y 编号	厂商编号	制造厂商	说明	Pin/Package	Size	Organisation	Access Time	Supply Volt.
16898	A290011T-70	AMIC	Boot Sector Flash Memory	32P/DIP		128K*8	70ns	5V
46224	A29040B-70F	AMIC	快闪式记忆体	DIP-32P	2M	512*8	70	5V
46234	A29L160AUV-70F	AMIC	快闪式记忆体	48P/TSOP	2M	2M*8	70	3.3V
45049	A29L160UV-70F	AMIC	快闪式记忆体	TSOP48	2M*8	2M*8	70NS	3V
1493	AM28F010-150PC	AMD	1 megabit CMOS 12.0 volt, bulk erase flash memory	32P/DIP	1M	128K*8	150ns	5V



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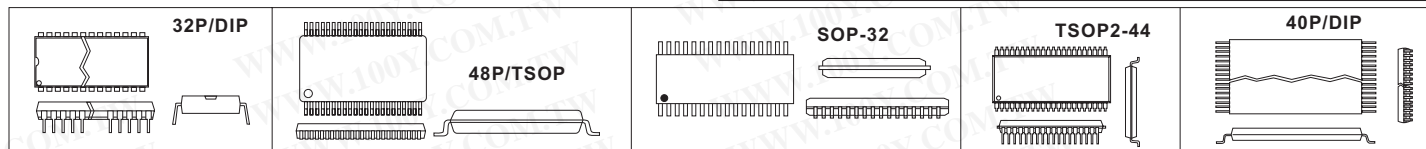
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100Y 编号	厂商编号	制造厂商	说明	Pin/Package	Size	Organisation	Access Time	Supply Volt.
10086	AM28F010A-120JC	AMD	1 megabit CMOS 12.0 volt, bulk erase flash memory with embedded algorithms	32P/PLCC	1M	128K*8	120ns	12V
18879	AM28F010A-90FC	AMD	1 megabit CMOS 12.0 volt, bulk erase flash memory with embedded algorithms	32P/TSOP	1M	128K*8	90ns	12V
18880	AM29DL323CB-90EI	AMD	2 megabit CMOS 5.0 volt-only boot sector flash memory	TSOP	32M			
18881	AM29F002BB-55EC	AMD	2 megabit CMOS 5.0 volt-only boot sector flash memory	32P/TSOP	2M	262144*8	55ns	5V
18882	AM29F002BT-120JC	AMD	2 megabit CMOS 5.0 volt-only boot sector flash memory	32P/PLCC	2M	262144*8	120ns	5V
18883	AM29F002BT-90JC	AMD	2 megabit CMOS 5.0 volt-only boot sector flash memory	32P/PLCC	2M	262144*8	90ns	5V
18885	AM29F002NT-90JC	AMD	2 megabit CMOS 5.0 volt-only boot sector flash memory	32P/PLCC	2M	262144*8	55ns	5V
1497	AM29F010-120PC	AMD	1 megabit CMOS 5.0 volt-only, uniform sector flash memory	32P/DIP	1M	128K*8	120	5V
47546	AM29F010-45PC	AMD	1 megabit CMOS 5.0 volt-only, uniform sector flash memory	32P/DIP	1M	128K*8	45ns	5V
3693	AM29F010-90PC	AMD	1 megabit CMOS 5.0 volt-only, uniform sector flash memory	32P/DIP	1M	128K*8	90ns	5V
32670	AM29F010A-70JC	AMD	1 megabit CMOS 5.0 volt-only, uniform sector flash memory	32P/PLCC	1M	128K*8	70	5V
18886	AM29F010A-70JI	AMD	1 megabit CMOS 5.0 volt-only, uniform sector flash memory	32P/PLCC	1M	128K*8	70	5V
18887	AM29F010B-120JC	AMD	1 megabit CMOS 5.0 volt-only, uniform sector flash memory	32P/PLCC	1M	128K*8	120	5V
18901	AM29F010B-70JD	AMD	1 M CMOS 5.0 volt-only, uniform sector flash memory(Pb Free)	32P/PLCC	1M	128K*8	70	5V
18902	AM29F010B-90JC	AMD	1 megabit CMOS 5.0 volt-only, uniform sector flash memory	32P/PLCC	1M	128K*8	90	5V
23518	AM29F016B-120EC	AMD	Sector Erase Flash Memory	48P/TSOP	16M	2,097,152*8Bit	70 ns	5.0 V
18903	AM29F016D-90EC	AMD	1 megabit CMOS 5.0 volt-only, uniform sector flash memory	32P/TSOP	16M	128K*8	90	5V
18904	AM29F040B-120EC	AMD	4 megabit CMOS 5.0 volt-only, uniform sector flash memory	32P/TSOP	4M	512K*8	120ns	5V
1501	AM29F040B-120PC	AMD	4 megabit CMOS 5.0 volt-only, uniform sector flash memory	32P/DIP	4M	512K*8	120ns	5V
23519	AM29F040B-70JC	AMD	Sector Erase Flash Memory	32P/PLCC	4 M	524,288*8Bit	55 ns	5.0 V
23520	AM29F040B-90JC	AMD	Sector Erase Flash Memory	32P/PLCC	4 M	524,288*8Bit	55 ns	5.0 V
1502	AM29F040B-90JI	AMD	4 megabit CMOS 5.0 volt-only, uniform sector flash memory	32P/PLCC	4M	512K*8	90ns	5V
32672	AM29F040B-90PD	AMD	4 megabit CMOS 5.0 volt-only, Sector Erase Flash Memory	32P/DIP	4M	524,288*8Bit	90	5.0 V
32673	AM29F080B-75SC	AMD	8 Megabit (1 M x 8-Bit) CMOS 5.0 Volt-only, Uniform Sector Flash Memory	44P/SO	8 M	1 M x 8-Bit	70ns	5 V
18905	AM29F200B-120EC	AMD	2 Megabit (256 K x 8-Bit/128 K x 16-Bit) CMOS 5.0 Volt-only, Boot Sector Flash Memory	48P/TSOP	2M	256*8	120ns	5V
18906	AM29F400AT-90EC	AMD	4 Megabit (524,288 x 8-Bit/262,144 x 16-Bit) CMOS 5.0 Volt-only, Sector Erase Flash Memory	48P/TSOP	4M	524,288 x 8	90ns	5V
18907	AM29F400BB-120SC	AMD	4 Megabit (512 K x 8-Bit/256 K x 16-Bit) CMOS 5.0 Volt-only Boot Sector Flash Memory	48P/TSOP	4M	512K x 8	120ns	5V
18908	AM29F400BB-90EC	AMD	4 Megabit (512 K x 8-Bit/256 K x 16-Bit) CMOS 5.0 Volt-only Boot Sector Flash Memory	48P/TSOP	8M	512K x 8	90ns	5V
32676	AM29F400BT-90SC	AMD	4 Megabit (512 K x 8-Bit/256 K x 16-Bit) CMOS 5.0 Volt-only Boot Sector Flash Memory	44P/SO	4M	512K x 8	90ns	5V
17486	AM29F800BT-70EC	AMD	CMOS 5.0 Volt-only, Boot Sector Flash Memory	48P/TSOP	1M	512 K x 16	70ns	5V
18913	AM29LV001BB-55EC	AMD	1 Megabit (128 K x 8-Bit) CMOS 3.0 Volt-only Boot Sector Flash Memory	32P/TSOP	1M	128 K x 8	55ns	5V
32678	AM29LV001BB-90JC	AMD	1 Megabit (128K x 8-Bit) CMOS 3.0 Volt-only Boot Sector Flash Memory	32P/PLCC	1M	128 K x 8	90ns	3.0 V
32679	AM29LV001BT-90JC	AMD	1 Megabit (128 K x 8-Bit) CMOS 3.0 Volt-only Boot Sector Flash Memory	32P/PLCC	1M	128 K x 8	90ns	3.0 V
39449	AM29LV010B-70JC	AMD	Uniform Sector Flash Memory	32P/PLCC	1 M	128 K*8Bit	55 ns	2.7-3.6V
23522	AM29LV010B-90JC	AMD	Uniform Sector Flash Memory	32P/PLCC	1 M	128 K*8Bit	55 ns	2.7-3.6V
3692	AM29LV040B-120JI	AMD	4 megabit CMOS 3.0 volt-only uniform 32-pin flash memory	32P/PLCC	4M	512K*8	120ns	3.3V
23523	AM29LV040B-70EC	AMD	Uniform Sector Flash Memory	32P/TSOP	4 M	512 K*8Bit	70 ns	2.7-3.6V
28789	AM29LV040B-70JC	AMD	Uniform Sector Flash Memory	32P/PLCC	4 M	512 K*8Bit	70 ns	2.7-3.6V
23524	AM29LV040B-90EC	AMD	Uniform Sector Flash Memory	32P/TSOP	4 M	512 K*8Bit	90ns	2.7-3.6V
23525	AM29LV081B-90EC	AMD	Uniform Sector Flash Memory	40P/TSOP	8 M	1 M*8Bit	70 ns	3.0V
32680	AM29LV160DB-70EC	AMD	16 Megabit CMOS 3.0 Volt-only Boot Sector Flash Memory	48P/TSOP	16M	2Mx8bit OR 1Mx16bit	70nS	2.7 to 3.6V
40412	AM29LV160DB-70ED	AMD	16 Megabit CMOS 3.0 Volt-only Boot Sector Flash Memory	48P/TSOP	16M	2Mx8bit OR 1Mx16bit	70nS	2.7 to 3.6V
28028	AM29LV160DB-90EC	AMD	16 Megabit CMOS 3.0 Volt-only Boot Sector Flash Memory	48P/TSOP	16MG	2Mx8bit OR 1Mx16bit	90nS	2.7 to 3.6V
23650	AM29LV160DT-70EC	AMD	Boot Sector Flash Memory	48P/TSOP	16 M	2 M*8Bit / 1 M*16Bit	70 ns	3.0V
23526	AM29LV160DT-90EC	AMD	Boot Sector Flash Memory	48P/TSOP	16 M	2 M*8Bit / 1 M*16Bit	90ns	3.0V
18914	AM29LV200BT-90SC	AMD	2 Megabit (256 K x 8-Bit/128 K x 16-Bit) CMOS 3.0 Volt-only Boot Sector Flash Memory	48P/TSOP	2M	256K*8 or 128k*16	90ns	5V
23527	AM29LV320DT-120EF	AMD	Boot Sector Flash Memory(Pb Free)	48P/TSOP	32 M	4 M*8Bit / 2 M*16Bit	120 ns	3.0V
39781	AM29LV320DT-90EF	AMD	快闪式记忆体(Pb Free)	48P/TSOP	32M	4 M*8Bit / 2 M*16Bit	90ns	3V
32682	AM29LV400BB90SC	AMD	4 Megabit (512 K x 8-Bit/256 K x 16-Bit) CMOS 3.0 Volt-only Boot Sector Flash Memory	44P/SO	4M	512 K x 8-Bit/256 K x 16-Bit	90ns	3 V
23528	AM29LV800DB-70EC	AMD	Boot Sector Flash Memory	48P/TSOP	8 M	1 M*8Bit / 512 K*16Bit	70 ns	3.0V
18917	AM29LV800DB-90ED	AMD	8 M CMOS 3.0 Volt-only Boot Sector Flash Memory(Pb Free)	48P/TSOP	8M	512*16	90ns	5V



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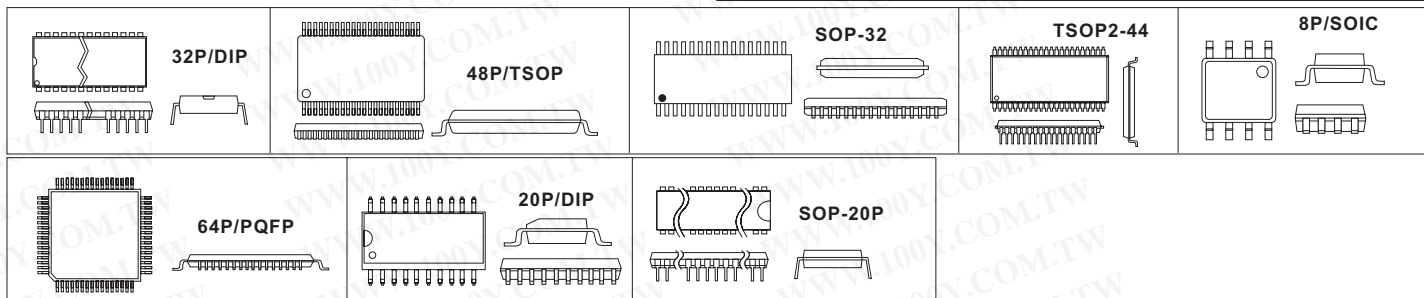
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# 记忆IC

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100Y 编号	厂商编号	制造厂商	说明	Pin/Package	Size	Organisation	Access Time	Supply Volt.
23529	AM29LV800DT-70EC	AMD	Boot Sector Flash Memory	48P/TSOP	8 M	1 M*8Bit / 512 K*16Bit	70 ns	3.0V
18919	AS29F010-15LC	Alliance	5V 128Kx8 CMOS Flash EEPROM	32P/PLCC		128K*8	150ns	5V
18920	AS29F040-120LC	Alliance	5V 512K*8 CMOS Flash EEPROM	32P/PLCC		512K*8	90ns	5V
18926	AT29C010A-15JC	ATMEL	1-megabit (128K x 8) 5-volt Only Flash Memory	32P/PLCC	1M	128K*8	150ns	5V
16609	AT29C010A-15PC	ATMEL	1-megabit (128Kx8) 5-volt Onoy Flash Memory	32P/DIP	1M	128K*8	150ns	5V
23536	AT29C010A-70JC	ATMEL	Flash Memory	32P/PLCC	1M	128K*8	70 ns	5V
16610	AT29C020-12PC	ATMEL	2-megabit (256Kx8) 5-volt Only Flash Memory	32P/DIP	2M	256K*8	120ns	5V
1496	AT29C020-90JI	ATMEL	2-Megabit (256K x 8) 5-volt only CMOS flash memory	32P/PLCC	2M	256K*8	90ns	5V
22461	AT29C040A-12TC	ATMEL	4-megabit 5-volt Only 256-byte Sector Flash Memory	32P/TSOP	4M	512K*8	-120 ns	5V
18929	AT29C040A-12TI	ATMEL	4-megabit (512K x 8) 5-volt Only 256-byte Sector Flash Memory	32P/TSOP	4M	512K*8	120ns	5V
8809	AT29C256-12JI	ATMEL	256(32 x 8) 5-volt only CMOS flash memory	32P/PLCC	256K	32K*8	120ns	5V
31582	AT29C512-90TI	ATMEL	512K (64K x 8) 5-volt only CMOS flash memory,50mA to 0.1mA	32P/TSOP	512K	64K*8	90ns	5V
18933	AT29LV020-20TI	ATMEL	2-Megabit (256K x 8)3-volt Only Flash Memory	32P/TSOP	2M	256K*8	200ns	3V
32707	AT29LV040A-20TC	ATMEL	4 Megabit (512K x 8) 3-volt Only 256 Byte Sector CMOS Flash Memory	32P/TSOP	4M	512K x 8	200 ns	3 V
32709	AT29LV256-20JC	ATMEL	256K (32K x 8) 3-volt Only CMOS Flash Memory	32P/PLCC	256K	32K x 8	200 ns	3 V
8096	AT29LV512-15JC	ATMEL	512K (64Kx8) 3-volt Only Flash Memory	32P/PLCC	512K	64K*8	150ns	3.3V
32711	AT29LV512-20JC	ATMEL	512K (64Kx8) 3-volt Only Flash Memory	32P/PLCC	512K	64K*8	120ns	3 V
18930	AT45DB011B-SC	ATMEL	1-megabit 2.7-volt Only DataFlash	8P/SOIC	1M			3.3V
41468	AT45DB011B-SI	ATMEL	AT45DB011B-SI 快闪式记忆体	8P/SOIC				2.7V-3.6V
23537	AT45DB011B-XC	ATMEL	DataFlash	14P/TSSOP	1M			2.7V
22468	AT45DB041A-RC	ATMEL	4-megabit 2.7-volt Only Serial DataFlash	28P/SOIC	4M		7 ms Typical	2.7V~3.6V
22469	AT45DB081A-TC	ATMEL	8M 2.7V Only Serial DataFlash	32P/TSOP	8M	4096 Pages of 264-bytes each	10MHz	2.7~ 3.6V
46240	AT45DB081B-TU	ATMEL	快闪式记忆体	TSOP-28				2.7V
18934	AT49BV512-12JC	ATMEL	512K (64K x 8) Single 2.7-volt Battery-Voltage Flash Memory	32P/PLCC	512K	64K*8	120ns	2.7V
18935	AT49F002NT-70JC	ATMEL	2-Megabit (256K x 8) 5-volt Only CMOS Flash Memory	32P/PLCC	2M	256K x 8	70ns	5V
8811	AT49F002NT-70PC	ATMEL	2-Megabit(256K x 8) 5-volt only CMOS flash memory	32P/DIP	2M	256K*8	70ns	5V
18936	AT49F002NT-90PC	ATMEL	2-Megabit (256K x 8) 5-volt Only CMOS Flash Memory	32P/DIP	2M	256K x 8	90ns	5V
18937	AT49F002NT-90TC	ATMEL	2-Megabit (256K x 8) 5-volt Only CMOS Flash Memory	32P/TSOP	2M	256K x 8	90ns	5V
8808	AT49F010-90JC	ATMEL	1-Megabit (128K x 8) 5-volt only CMOS flash memory	32P/PLCC	1M	128K*8	90ns	5V
8807	AT49F020-70JC	ATMEL	2-Megabit (256K x 8) 5-volt only CMOS flash memory	32P/PLCC	2M	262144*8	70ns	5V
40303	AT49F020-70TC	ATMEL	2-Megabit (256K x 8) 5-volt only CMOS flash memory	32P/TSOP	2M	262144*8	70ns	5V
30819	AT49F020-90TC	ATMEL	FLASH 2Mb 90ns PLCC	32P/TSOP	2M		90nS	5V
16291	AT49F040-90JC	ATMEL	4-megabit (512Kx8) 5-volt Only Flash Memory	32P/PLCC	4M	512K*8	90ns	5V
18889	AT49F8192-90TC	ATMEL	8-Megabit (512K x 16) 5-volt Only Flash Memory	48P/TSOP	1M	128K*8	90ns	5V
23539	AT49LV040-90JC	ATMEL	Battery-Voltage Flash Memory	32P/PLCC	512K*8	4M	70 ns	2.7V
46261	ATMEGA128L-8AU	ATMEL	快闪式记忆体	TQFP and 64-pad		128K		2.7-5.5V
46262	ATMEGA16-16AU	ATMEL	快闪式记忆体	44P/TQFP		128K	16	4.5-5.5
46271	ATTINY2313-20SU	ATMEL	快闪式记忆体	SOP-20P	16K	2K*8	20NS	4.5-5.5V
46272	ATTINY2313V-10PU	ATMEL	快闪式记忆体	DIP-20P	16K	2K*8	20NS	2.7-5.5
18890	CAT28F020N-12	CATALYST	FLASH	32P/PLCC	2M	128K*8	120ns	5V
17499	DA0064M		DiskOnModule		64MB			
18891	DA28F320J5-120	INTEL	5 Volt Intel StrataFlashR Memory	56P/SSOP	32M	128K	120ns	5V
42015	DS2505P	DALLAS	16-kbit Add-Only Memory	6-pin TSOC				
12818	DT28F160S5-70	INTEL	Word-wide FlashFile memory	56P-SSOP	16M	2M*8/1M*16	75ns	5V
12580	E28F002BV-B60ES	INTEL	2-Mbit (128K x 16, 256K x 8) SmartVoltage boot block flash memory family	40P-TSOP	2Mb	256K*8	60ns	5V
12583	E28F002BV-T60ES	INTEL	2-Mbit (128K x 16, 256K x 8) SmartVoltage boot block flash memory family	40P-TSOP	2Mb	256K*8	60ns	5V
12718	E28F004B5B60	INTEL	Smart 5 boot block flash memory 4 Mbit	40P-TSOP	4M	512K*8	60ns	5V
12721	E28F004B5T60	INTEL	Smart 5 boot block flash memory 4 Mbit.	40P-TSOP	4M	512K*8	60ns	5V
12911	E28F004BV-B60ES	INTEL	4-Mbit (256K x 16, 512K x 8) SmartVoltage boot block flash memory family	40P-TSOP	4M	512K*8	60ns	5V
12909	E28F004BVT60ES	INTEL	4-Mbit (256K x 16, 512K x 8) SmartVoltage boot block flash memory family.	40P-TSOP	4M	512K*8/256K*16	60ns	5V
12722	E28F004S3120	INTEL	Smart 3 FlashFile memory 4 Mbit	40P-TSOP	4M	512K*8	60ns	5V
12719	E28F004S585	INTEL	Byte-wide smart 5 FlashFile memory 4 Mbit	40P-TSOP	4M	512K*8	85ns	5V
18893	E28F008SA-120	INTEL	5 Volt Intel StrataFlashR Memory	40P/TSOP	8M	64K	120ns	5V
18892	E28F016S3-120	INTEL	快闪式记忆体	TSOP	16M	128K	70ns	5V



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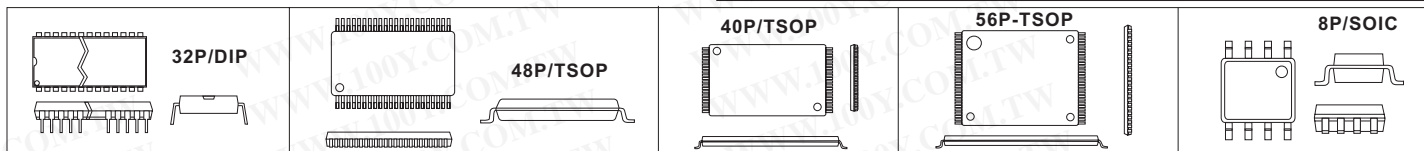
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100Y 编号	厂商编号	制造厂商	说明	Pin/Package	Size	Organisation	Access Time	Supply Volt.
18894	E28F016SA-70	INTEL	Word-wide FlashFile memory	56P-TSOP	16M	2M*8/1M*16	70ns	5V
12872	E28F016XD-85	INTEL	16-Mbit (1 Mbit x 16) DRAM-interface flash memory	56P-TSOP	16M	1M*16	85ns	5V
18895	E28F128J3A-150	INTEL	4-Mbit (256K x 16, 512K x 8) SmartVoltage boot block flash memory family	56P/TSOP	128M	512K*8/256K*16	60ns	3V
12579	E28F200BV-B60ES	INTEL	2-Mbit (128K x 16, 256K x 8) SmartVoltage boot block flash memory family	56P/TSOP	2M	256K*8/ 128K*16	60ns	5V
12582	E28F200BV-T60ES	INTEL	2-Mbit (128K x 16, 256K x 8) SmartVoltage boot block flash memory family.	56P/TSOP	2M	256K*8/128K*16	60ns	5V
12581	E28F200CV-B60ES	INTEL	2-Mbit (128K x 16, 256K x 8) SmartVoltage Boot Block Flash Memory Family	48P/TSOP	2M	256K*8	60ns	5V
12571	E28F200CV-T60ES	INTEL	2-Mbit (128K x 16, 256K x 8) SmartVoltage boot block flash memory family	48P/TSOP	2M	256K*8/128K*16	60ns	5V
18896	E28F320J3A-110	INTEL	32 Megabit Intel StrataFlashR Memory	56P/TSOP	32M	340*161	110ns	5V
12720	E28F400B5B60	INTEL	Smart 5 boot block flash memory 4 Mbit	48P/TSOP	4M	512K*8/256K*16	60ns	5V
12871	E28F400B5B80	INTEL	Smart 5 boot block flash memory 4 Mbit.	48P/TSOP	4M	512K*8	80ns	5V
12819	E28F400B5T60	INTEL	Smart 5 boot block flash memory	56P/TSOP	4M	512K*8/256K*16	60ns	5V
12820	E28F400B5T80	INTEL	Smart 5 boot block flash memory 4 Mbit	56P/TSOP	4M	512K*8/256K*16	80ns	5V
12907	E28F400BV-T60ES	INTEL	4-Mbit (256K x 16, 512K x 8) SmartVoltage boot block flash memory family.	56P/TSOP	4M	512K*8/256K*16	60ns	5V
12908	E28F400CV-B60ES	INTEL	4-Mbit (256K x 16, 512K x 8) SmartVoltage boot block flash memory family	48P/TSOP	4M	512K*8/256K*16	60ns	5V
12910	E28F400CV-T60ES	INTEL	4-Mbit (256K x 16, 512K x 8) SmartVoltage boot block flash memory family	48P/TSOP	4M	512K*8/256K*16	60ns	5V
42110	E28F640J3A-120	INTEL	FLASH	56P/TSOP	64M		120ns	3V
18897	E28F800CVT-70	INTEL	FLASH	48P/TSOP	8M	512*16	70ns	5V
18898	F28F010C-90	INTEL	FLASH MEMORY	32P/TSOP	1M	128K*8	90ns	5V
18899	GT28F800B3-B90	INTEL	FLASH	40P/TSOP	8M	1024*8	90ns	3V
41480	HY27SF081G2M-T	HYNIX	HIGH DENSITY NAND FLASH MEMORIES	48 - USOP1	12 x 17 mm.	300us	2ms	1.70 - 1.95 Volt
41479	HY27UF081G2M-T	HYNIX	HIGH DENSITY NAND FLASH MEMORIES	48 - TSOP1	12 x 20 mm	300us	2ms	2.7V - 3.6 Volt
41482	HY27UF082G2M-T	HYNIX	HIGH DENSITY NAND FLASH MEMORIES	48 - TSOP1	12 x 20 mm	200us	2ms	2.7V - 3.6 Volt
44351	HY27UF084G2M-TPC B	HYNIX	HIGH DENSITY NAND FLASH MEMORIES	48 - TSOP1	12 x 20 mm	200us	2ms	2.7V - 3.6 Volt
41490	HY27UF084G2M-TPC B	HYNIX	HIGH DENSITY NAND FLASH MEMORIES	48 - TSOP1	12 x 20 mm	200us	2ms	2.7V - 3.6 Volt
41485	HY27UF162G2M-T	HYNIX	HIGH DENSITY NAND FLASH MEMORIES	48 - TSOP1	12 x 20 mm	200us	2ms	2.7V - 3.6 Volt
41456	HY27US08121A-TP	HYNIX	HIGH DENSITY NAND Flash MEMORIES	48-Pin TSOP1	12 x 20 x 1.2 mm		2ms	2.7 to 3.6V
41465	HY27US08561A	HYNIX	a 32Mx8bit with spare 8Mbit capacity	48-Pin TSOP1		x8		2.7v-3.6v
41437	HY27US08561M	HYNIX	256Mbit (32Mx8bit / 16Mx16bit) NAND Flash Memory	48P-WSOP1	12*17*0.7MM			1.8V-3.3V
22624	IS28F010-45PL	ISSI	131,072 x 8 CMOS FLASH MEMORY	32P/PLCC			45ns	-0.2-7V
15531	IS28F010A-45W	ISSI	"ISSI" FLASH memory	32P/DIP	1Mb	128K*8	45ns	5V
1460	JS28F160C3BD-70	INTEL	Flash RAM(Pb Free)	TSOP	160M			
1459	JS28F160C3TD70	INTEL	Flash RAM(Pb Free)	TSOP	160M			
1452	JS28F320C3BD-70	INTEL	Flash RAM(Pb Free)	TSOP	320M			
40950	K9F1G08U0A-PIB0	SAMSUNG	128M x 8 Bit NAND Flash Memory	48-pin TSOP1	2K-Byte	X8	30ns	2.7 ~ 3.6V
16897	K9F6408UOC-TCB0	SAMSUNG	Flash	44P/TSOP		8M*8	50ns	2.7V
18938	KM29N040T	SAMSUNG	FLASH	TSOP	4M			
18939	LH28F008SAT-85	SHARP	FLASH MEMORY	40P/TSOP	8M	1MB*8	85ns	5V
18940	LH28F008SCHT-TL12	SHARP	8M(X8)FLASH MEMORY	40P/TSOP	8M	8M*8	120ns	5V
18941	LH28F160S3T-L10	SHARP	16M(x8/x16)FLASH MEMORY	56P/TSOP	16M	2M*8	100ns	2.7V
18942	LH28F160S5HNS-L70	SHARP	16M(x8/x16)FLASH MEMORY	56P/SSOP	16M	2M*8	70ns	2.7V
18944	LH28F160S5TL-10A	SHARP	16 M-bit (2 MB x 8/1 MB x 16) Smart 5 Flash Memories (Fast Programming)	56P/TSOP	16M	2M*8 or 1M*16	100ns	5V
18945	LH28F800BVHE-BTL90	SHARP	8M-BIT(1Mbit*8/512Kbit*16) Smart3 Flash MEMORY	48P/TSOP	8M	1M*8 or 512K*16	90ns	2.7V
18946	LH28F800SUT-10	SHARP	8M-BIT(1Mbit*8/512Kbit*16) Smart3 Flash MEMORY		8M		100ns	
23371	M25P10-AVMN6	ST(SGS)	Low Voltage, Serial Flash Memory With 40 MHz SPI Bus Interface	8P/SOIC	1 Mbit	128*8		2.7-3.6V
42758	M25P20VMN6	ST(SGS)	2 Mbit, low voltage, Serial Flash memory with 50MHz SPI bus interface	SO-8	2M	256K*8-Series	50MHz	2.7 to 3.6V
26835	M25P40-VMN6	ST(SGS)	Low Voltage, Serial Flash Memory With 25 MHz SPI Bus Interface	8P/SO	4M	512K*8-Series	40MHz	2.7-3.6V



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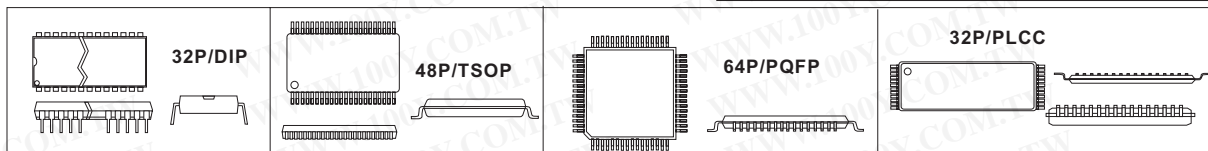
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18948	M28F101-100N1	ST(SGS)	Memory configuration 128Kx8 Memory type Flash Memory size 1 M-bit 1Mb (128K8) FLASH memory	32P/TSOP	1M	128K*8	100ns	5V
1536	M28F101-150P1	ST(SGS)	Memory configuration 128Kx8 Memory type Flash Memory size 1 M-bit 1Mb (128K8) FLASH memory	32P/DIP	1M	128K*8	150ns	5V
18949	M28F201-120K1	ST(SGS)	FLASH	32P/PLCC			120ns	5V
18950	M28F201-150K1	ST(SGS)	FLASH	32P/PLCC			150ns	5V
23573	M29F010B-120K1	ST(SGS)	Single Supply Flash Memory	32P/PLCC	128Kb*8	1 M	120ns	5V±10%
23574	M29F010B-90K1	ST(SGS)	Single Supply Flash Memory	32P/PLCC	1 Mbit	128Kb *8	90ns	5V±10%
34852	M29F040B-55K1	ST(SGS)	4 Mbit (512Kb x8, Uniform Block) Single Supply Flash Memory	32P/PLCC	4M	512K*8	55 ns	5V
16608	M29F040B-70K1	ST(SGS)	4 Mbit (512Kb x8, Uniform Block) Single Supply Flash Memory	32P/PLCC	4M	512K*8	70ns	5V
22204	M29F040B-70K6	ST(SGS)	4 Mbit (512Kb x8, Uniform Block) Single Supply Flash Memory	32P/PLCC	4M	512K*8	70ns	5V
34854	M29F040B-70N1	ST(SGS)	4 Mbit (512Kb x8, Uniform Block) Single Supply Flash Memory	TSOP32: 8 x 20 mm	4M	512Kb x8	70ns	5V
18951	M29F040B-90K1	ST(SGS)	4 Mbit (512Kb x8, Uniform Block) Single Supply Flash Memory	32P/PLCC	4M	512K*8	90ns	5V
23575	M29F040B-90K6	ST(SGS)	Single Supply Flash Memory	32P/PLCC	512Kb*8	4 Mbit	90ns	5V ± 10%
18952	M29F800AB-90N1	ST(SGS)	8 Mbit (1Mb x8 or 512Kb x16, Boot Block) Single Supply Flash Memory	48P/TSOP	8M	1M*8 or 512K*16	90ns	5V
18953	M29W160DB-90N1	ST(SGS)	16 Mbit (2Mb x8 or 1Mb x16, Boot Block) 3V Supply Flash Memory	48P/TSOP	16M	2M*8 or 1M*16	90ns	3V
23576	M29W160DT-70N1	ST(SGS)	Supply Flash Memory	48P/TSOP	2Mb *8 or 1Mb *16	16 M	70ns	2.7-3.6V
23578	M29W160DT-90N1	ST(SGS)	Supply Flash Memory	48P/TSOP	2Mb *8 or 1Mb *16	16 M	90ns	2.7-3.6V
23579	M29W160EB-70N6	ST(SGS)	Supply Flash Memory	48P/TSOP	2Mb *8 or 1Mb *16	16 M	70ns	2.7-3.6V
23583	M29W320DB-70N6	ST(SGS)	Supply Flash Memory	48P/TSOP	4Mb *8 or 2Mb *16	32 M	70ns	2.7-3.6V
18954	M29W320DB-90N6	ST(SGS)	32 Mbit (4Mb x8 or 2Mb x16, Boot Block) 3V Supply Flash Memory	48P/TSOP	32M	4M*8 or 2M*16	90ns	3V
18955	M29W320DT-70N6	ST(SGS)	32 Mbit (4Mb x8 or 2Mb x16, Boot Block) 3V Supply Flash Memory	48P/TSOP	32M	4M*8 or 2M*16	70ns	3V
23584	M29W800AB-120N1	ST(SGS)	Low Voltage Single Supply Flash Memory	48P/TSOP	1Mb*8 or 512Kb*16	8 M	120ns	2.7V-3.6V
18956	M29W800AB-90N1	ST(SGS)	8 Mbit (1Mb x8 or 512Kb x16, Boot Block) Low Voltage Single Supply Flash Memory	48P/TSOP	8M	1M*8 or 512K*16	70ns	3V
18957	M29W800AB-90N6	ST(SGS)	8 Mbit (1Mb x8 or 512Kb x16, Boot Block) Low Voltage Single Supply Flash Memory	48P/TSOP	8M	1M*8 or 512K*16	90ns	3V
23585	M29W800DB-70N1	ST(SGS)	Supply Flash Memory	48P/TSOP	1Mb*8 or 512Kb*16	8 M	70ns	2.7V-3.6V
22701	M29W800DT-70N6E	ST(SGS)	Supply Flash Memory	48P/TSOP	8 Mbit	1Mb*8	70ns	2.7-3.6V
18958	MBM29F040A-12PD	FUJITSU	4M(512K*8) BIT FLASH MEMORY	32P/PLCC	4M	512K*8	120ns	5V
18959	MBM29F040A-12PFTN-X	FUJITSU	4M(512K*8) BIT FLASH MEMORY	32P/TSOP	4M	512K*8	120ns	5V
18960	MBM29F080A-90PFTN	FUJITSU	8M (1M*8) BIT FLASH MEMORY	48P/TSOP	8M	1M*8	90ns	5V
18961	MBM29F400TA-90PFTN	FUJITSU	4M(512K*8/256K*16)BIT CMOS FLASH MEMORY	48P/TSOP	4M	512K*8 or 256K*16	90ns	5V
18962	MBM29LV160BE-70TN-E1	FUJITSU	16M CMOS FLASH MEMORY(Pb Free)	48P/TSOP	16M	2M*8 or 1M*16	70ns	3V
23589	MBM29LV160TE-70TN	FUJITSU	FLASH MEMORY	48P/TSOP	2M*8/1M*16BIT	16M	70 ns	3.0 V
23590	MBM29LV400B-10PFTN	FUJITSU	FLASH MEMORY	48P/TSOP	512K*8 / 256K*16	4M	120 ns	3.0 V
23591	MBM29LV400BC-55PFTN	FUJITSU	FLASH MEMORY	48P/TSOP	512K*8 / 256K*16	4M	55ns	3.0 V
23592	MBM29LV800BA-70PFTN	FUJITSU	FLASH MEMORY	48P/TSOP	8M	1M*8/512K*16	90 ns	3.0 V
38942	MD2200-D02		DiskOnChip2000	32P/DIP				
34483	MD2202-D16		DiskOnChip2000	32P/DIP	16M			
36070	MD2202-D32-X		DiskOnChip2000	32P/DIP	32M			
40227	MSC1210Y4PAGT	T.I.	Precision Analog-to-Digital Converter (ADC) with 8051 Microcontroller and Flash Memory	TQFP64				
28728	MX26LV800BTC-55	MXIC	3V ONLY HIGH SPEED eLiteFlash MEMORLY	48P/TSOP	8M	1Mx8/512K x16	55ns	3.0-3.6V
28727	MX26LV800TTC-55	MXIC	3V ONLY HIGH SPEED eLiteFlash MEMORLY	48P/TSOP	8M	1Mx8/512K x16	55ns	3.0-3.6V
22751	MX28F1000PQC-12C4	MXIC	CMOS FLASH MEMORY	32P/PLCC	128K*8	1M	120ns	5V
22752	MX28F2000PQC-12C4	MXIC	CMOS FLASH MEMORY	32P/PLCC	256K*8	2M	120nS	-0.5-7V
18963	MX28F2000QC-12C4	MXIC	FLASH	PLCC			120ns	
22753	MX29F002TQC-12	MXIC	CMOS FLASH MEMORY	32P/PLCC	256K*8	2M	120nS	5V
22754	MX29F002TQC-90	MXIC	CMOS FLASH MEMORY	32P/PLCC	256K*8	2M	90nS	5V
49109	MX29F040PC-90	MXIC	MXIC_32P/DIP	32P/DIP				
22764	MX29F040QC-12	MXIC	CMOS EQUAL SECTOR FLASH MEMORY	32P/PLCC	512K*8	4M	120nS	-0.5-7V
22765	MX29F040QC-90	MXIC	CMOS EQUAL SECTOR FLASH MEMORY	32P/PLCC	512K*8	4M	90nS	-0.5-7V
28723	MX29LV040QC-70	MXIC	3V ONLY EQUAL SECTOR FLASH MEMORY	32P/PLCC	4M	512K x 8	70ns	2.7-3.6V
23594	MX29LV160ABTC-70	MXIC	CMOS SINGLE VOLTAGE 3V ONLY FLASH MEMORY	48P/TSOP	2M*8/1M*16	16M	70ns	3.0V
18964	MX29LV160ABTC-90	MXIC	FLASH	48P/TSOP			90ns	
23595	MX29LV160ATTC-90	MXIC	CMOS SINGLE VOLTAGE 3V ONLY FLASH MEMORY	48P/TSOP	2M*8/1M*16	16M	90ns	2.7V-3.6V
46341	MX29LV160CBTC-70G	MXIC	快闪式记忆体	48P/TSOP	160MB		70ns	3V



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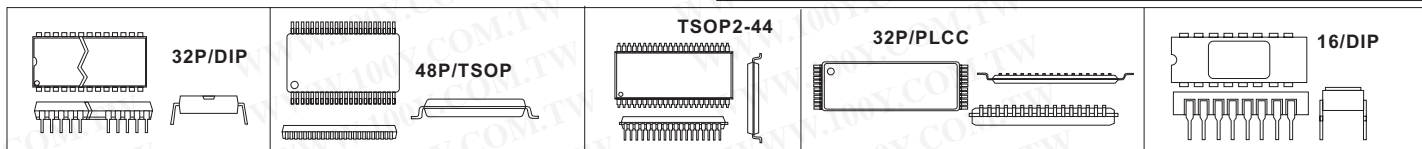
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## 快闪式记忆体

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100Y 编号	厂商编号	制造厂商	说明	Pin/Package	Size	Organisation	Access Time	Supply Volt.
18968	MX29LV320ABTC-90	MXIC	32M-BIT [4M x 8 / 2M x 16] SINGLE VOLTAGE 3V ONLY FLASH MEMORY	48P/TSOP	32M	4M*8 or 2M*16	90ns	3V
46342	MX29LV320CBTC-70G	MXIC	快闪式记忆体	TSOP/48	32MB		70ns	3V
28650	MX29LV320TTC-90	MXIC	SINGLE VOLTAGE 3V ONLY FLASH MEMORY	48P/TSOP	32M	4M x 8 / 2M x 16	90ns	2.7 ~3.6
28725	MX29LV400BTC-70	MXIC	3V ONLY FLASH MEMORY	48P/TSOP	4M	512K x 8 / 256K x 16	70ns	2.7~3.6V
28649	MX29LV400TTC-90	MXIC	CMOS SINGLE VOLTAGE 3V ONLY FLASH MEMORY	48P/TSOP	4M	512K*8 / 256K* 16	90ns	2.7V~3.6V
23596	MX29LV800BTC-70	MXIC	CMOS SINGLE VOLTAGE 3V ONLY FLASH MEMORY	48P/TSOP	1M*8/512K *16	8M	70ns	3.0V
23597	MX29LV800BTC-90	MXIC	CMOS SINGLE VOLTAGE 3V ONLY FLASH MEMORY	48P/TSOP	1M*8/512K *16	8M	90ns	3.0V
23598	MX29LV800TTC-90	MXIC	CMOS SINGLE VOLTAGE 3V ONLY FLASH MEMORY	48P/TSOP	1M*8/512K *16	8M	90ns	3.0V
18969	N28F001BXT-150	INTEL	快闪式记忆体	32P/PLCC			150ns	
18970	N28F010-120	INTEL	FLASH	32P/PLCC			120ns	
18971	N28F020-120	INTEL	FLASH	PLCC	2M			
18972	N28F020-150	INTEL	CMOS FLASH MEMORY	32P/PLCC	2M	256K*8	150ns	
46764	N82S131N	PHILIPS	飞利浦_快闪式记忆体	16P/DIP	512*4	2K- Bit	50 ns	7V
40189	P28F001BXT-120	INTEL	FLASH MEMORY	32P/DIP	1M			
18973	P28F001BXT-150	INTEL	FLASH	32P/DIP	1M			
12823	PA28F008S585	INTEL	Byte-wide smart 5 FlashFile memory 8 Mbit	44P/PSOP	8M	1M*8	85ns	5V
12808	PA28F016S3120	INTEL	Smart 3 FlashFile memory 16 Mbit.	44P/PSOP	16M	2M*8/1M*16	120ns	3.3V
12814	PA28F016S585	INTEL	Byte-wide smart 5 FlashFile memory 16 Mbit.	44P/PSOP	16M	2M*8/1M*16	85ns	5V
12578	PA28F200B5-T60	INTEL	Smart 5 boot block flash memory 2 Mbit.	44P/PSOP	2M	256K*8/ 128K*16	60ns	5V
12874	PA28F400B5B60	INTEL	Smart 5 boot block flash memory 4 Mbit	44P/PSOP	4M	512K*8/256K*16	60ns	5V
12873	PA28F400B5B80	INTEL	Smart 5 boot block flash memory 4 Mbit.	44P/PSOP	4M	512K*8/256K*16	80ns	5V
12822	PA28F400B5T60	INTEL	Smart 5 boot block flash memory 4 Mbit.	44P/PSOP	4M	512K*8/256K*16	80ns	5V
12821	PA28F400B5T80	INTEL	Smart 5 boot block flash memory 4 Mbit	44P/PSOP	4M	512K*8/256K*16	80ns	5V
18977	PA28F800B5-B70	INTEL	FLASH	SOP	8M			5V
18978	PA28F800B5-T70	INTEL	SMART 5 BOOT BLOCK FLASH MEMORY FAMILY 8 MBIT	SOP	8M			
34808	PC28F128J3C-120	INTEL	128M Flash RAM(Pb Free)	BGA	128M			
1428	PC28F128J3D75	INTEL	128M Flash RAM(Pb Free)	BGA	128M			
1466	PC28F640J3D75	INTEL	640M Flash RAM(Pb Free)	BGA	640M			
18979	RC28F128J3C120	INTEL	FLASH	BGA				
28838	RC28F320J3D75	INTEL	快闪式记忆体	BGA	320M			
28839	RC28F640J3D75	INTEL	3V 快闪式记忆体	BGA				3V
37547	SST28SF040A-120-4C-NH	SST	4 Mbit (512K x8) SuperFlash EEPROM	32P/PLCC	4M	512K*8	120ns	5V
48720	SST28SF040A-90-4C-NH	SST	SST_4 Mbit (512K x8) SuperFlash EEPROM	32PIN/PLCC	4M	512K*8	90ns	4.5-5.5V
18980	SST28SF040A-90-4C-PH	SST	4 Mbit (512K x8) SuperFlash EEPROM	32P/DIP	4M	512K*8	90ns	5V
18981	SST29EE010-120-4C-NH	SST	1 Mbit (128K x8) Page-Write EEPROM	32P/PLCC	1M	128K*8	120ns	5V
18982	SST29EE010-90-4C-NH	SST	1 Mbit (128K x8) Page-Write EEPROM	32P/PLCC	1M	128K*8	90ns	5V
18983	SST29LE512-150-4C-NH	SST	1 Mbit (128K x8) Page-Write EEPROM	32P/PLCC	1M	128K*8	150ns	3V
46709	SST39LF040-45-4C-NH	SST	快闪式记忆体	32P/PLCC	4M		45ns	3-3.6V
46340	SST39LF512-45-4C-WHE	SST	快闪式记忆体	32P/TSOP	1M		45ns	3-3.6V
18984	SST39SF010A-70-4C-NHE	SST	1 Mbit (x8) Multi-Purpose Flash(Pb Free)	32P/PLCC	1M	128K*8	90ns	5V
16611	SST39SF020A-70-4C-NH	SST	SST_2 Mbit (x8) Multi-Purpose Flash	32P/PLCC	2M	128K*8	70ns	5V
18985	SST39SF020A-70-4C-NHE	SST	SST_2 Mbit (x8) Multi-Purpose Flash	32P/PLCC	2M	128K*8	70ns	5V
16612	SST39SF020A-70-4C-PH	SST	Multi-purpose flash	32P/DIP	2M	128K*8	70ns	5V
18986	SST39SF512-70-4C-NH	SST	512 Kbit (x8) Multi-Purpose Flash	32P/PLCC		512K*8	70ns	5V
18987	SST39SF512-90-4C-NH	SST	512 Kbit (x8) Multi-Purpose Flash	32P/PLCC		512K*8	90ns	5V
35410	SST39VF010-70-4C-NHE	SST	Multi-Purpose Flash(Pb Free)	32P/PLCC	1M		70ns	2.7~3.6V
23604	SST39VF010-70-4C-WHE	SST	Multi-Purpose Flash(Pb Free)	32P/TSOP	1 M		70ns	2.7~3.6V
22838	SST39VF010-90	SST	Multi-Purpose Flash	32P/TSOP	128*8	1Mbit	90ns	2.7~3.6
18988	SST39VF020-70-4C-NH	SST	2Mbit (x8) Multi-Purpose Flash	32P/PLCC	2M	256K*8	70ns	2.7V
46338	SST39VF020-70-4C-NHE	SST	快闪式记忆体	32P/PLCC	1M		70ns	2.7~3.6V
46337	SST39VF020-70-4C-WHE	SST	快闪式记忆体	32P/TSOP	1 M		70ns	2.7~3.6V
18989	SST39VF040-70-4C-NHE	SST	4Mbit (x8) Multi-Purpose Flash(Pb Free)	32P/PLCC	4M	512K*8	70ns	2.7V
28222	SST39VF040-70-4C-WH	SST	4Mbit (x8) Multi-Purpose Flash	32P/TSOP	4M	512K*8	70ns	2.7V
44922	SST39VF512-70-4C-NHE	SST	快闪式记忆体	32PLCC	512 K		70ns	2.7-3.6V
23605	SST39VF512-70-4C-WH	SST	Multi-Purpose Flash	32P/TSOP	512 K		70ns	2.7-3.6V
23606	SST39VF800A-70-4C-B3K	SST	Multi-Purpose Flash	48P/TFBGA	8M		70ns	2.7-3.6V
23608	SST39VF800A-70-4C-EK	SST	Multi-Purpose Flash	48P/TSOP	8M		70ns	2.7-3.6V
46339	SST49LF002B-33-4C-NHE	SST	快闪式记忆体	32P/PLCC	4M		33 MHz	3.0-3.6V
23609	SST49LF004A-33-4C-NH	SST	Flash RAM	32P/PLCC	4M		33 MHz	3.0-3.6V
15922	SST49LF004B-33-4C-NHE	SST	Flash RAM(Pb Free)	32P/PLCC	4M		33 MHz	3.0-3.6V
24285	SST49LF020A-33-4C-NH	SST	2 Mbit LPC flash Flash	32P/PLCC	2Mbit	256Kx8	120ns	3.0-3.6V
18993	T28F160C3BA110	INTEL	FLASH	TSOP	16M			



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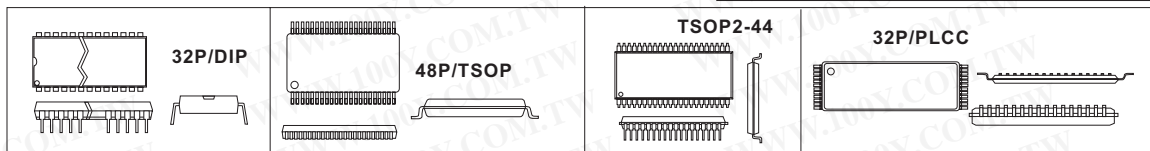
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# 记忆IC

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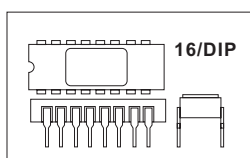
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100Y 编号	厂商编号	制造厂商	说明	Pin/Package	Size	Organisation	Access Time	Supply Volt.
18644	TC58DVM92A2TG00	TOSHIBA	4M CMOS flash memory(Pb Free)	TSOP	4Mb	512K*8		
23610	TC58V64BFT	TOSHIBA	CMOS NAND EEPROM	44P/TSOP	8M *8 BIT	64M		2.7 V ~3.6 V
18992	TE28F016B3TA110	INTEL	FLASH	TSOP	16M			
18990	TE28F016B3TA90	INTEL	FLASH	TSOP	16M			3V
18991	TE28F128J3C150	INTEL	FLASH	TSOP	128M		150ns	
23613	TE28F160B3TA110	INTEL	3-Volt Advanced Boot Block Flash Memory	48P/TSOP	16M		110ns	3V
23614	TE28F160C3BA110	INTEL	Boot Block Flash Memory	48P/TSOP	16M		110ns	3V
18994	TE28F160C3BD-70	INTEL	FLASH	TSOP			70ns	
23615	TE28F160C3TC-70	INTEL	Boot Block Flash Memory	48P/TSOP	16M		70ns	3V
18995	TE28F160C3TD-70	INTEL	FLASH	TSOP			70ns	
12817	TE28F160S375	INTEL	Word-wide FlashFile memory	56P/TSOP	16M	2M*8/1M*16	75ns	5V
18996	TE28F320C3BA100	INTEL	FLASH	TSOP	32M		100ns	
18997	TE28F320C3BC-70	INTEL	FLASH	48P/TSOP			70ns	
23617	TE28F320C3BD70	INTEL	Boot Block Flash Memory	48P/TSOP	32M		70ns	3.0V
23620	TE28F320C3TD-70	INTEL	Boot Block Flash Memory	48P/TSOP	32M		70ns	3.0V
18998	TE28F400B3T110	INTEL	FLASH	TSOP	4M			
18999	TE28F640J3C-115	INTEL	FLASH	TSOP			115ns	
18974	TE28F800B3BA90	INTEL	FLASH	TSOP				
18975	TE28F800B5B-90	INTEL	FLASH	48P/TSOP				
18976	TE28F800C3B90	INTEL	Flash Memory	TSOP	4Mbit	256kbit*16	90ns	2.7~3.6V
19000	TMS28F010A-15C4FML	T.I.	1048576-BIT FLASH ELECTRICALLY ERASABLE PROGRAMMABLE READ-ONLY MEMORY	32P/PLCC	1M	128K*8	150ns	5.5V
19001	TMS28F010B-10C4FMQ	T.I.	131072 BY 8-BIT FLASH MEMORY	32P/PLCC	1M	131072 * 8	100ns	5.5V
19002	TMS28F010B-12C4FME	T.I.	131072 BY 8-BIT FLASH MEMORY	32P/PLCC	1M	131072 * 8	120ns	5.5V
19003	TMS28F010B-12C4FML	T.I.	131072 BY 8-BIT FLASH MEMORY	32P/PLCC	1M	131072 * 8	100ns	5.5V
19004	TMS28F010B-12C4FMQ	T.I.	131072 BY 8-BIT FLASH MEMORY	32P/PLCC	1M	131072 * 8	100ns	5.5V
19005	TMS28F010B-12C5FME	T.I.	131072 BY 8-BIT FLASH MEMORY	32P/PLCC	1M	131072 * 8	120ns	5.5V
19006	TMS28F010B-12C5FML	T.I.	131072 BY 8-BIT FLASH MEMORY	32P/PLCC	1M	131072 * 8	120ns	5.5V
19007	TMS28F010B-15C4FML	T.I.	131072 BY 8-BIT FLASH MEMORY	32P/PLCC	1M	131072 * 8	150ns	5.5V
19008	TMS28F010B-90C5FML	T.I.	131072 BY 8-BIT FLASH MEMORY	32P/PLCC	1M	131072*8	90ns	5.5V
23516	TMS28F512A-12C4FMQ	T.I.	FLASH MEMORY	32P/PLCC		65536 by 8 Bits	120 ns	5.5 V
19010	TMS28F512A-15C4FME	T.I.	FLASH MEMORY	32P/PLCC	512K	64K*8	150ns	5.5V
19011	TMS28F512A-15C4FML	T.I.	FLASH MEMORY	32P/PLCC	512K	64K*8	150ns	5.5V
11833	TMS28F512A-15FME	T.I.	FLASH MEMORY	32P/PLCC	512K	64K*8	100ns	5.5V
19009	TMS28F512A-15FMQ	T.I.	FLASH MEMORY	32P/PLCC	512K	64K*8	120ns	5.5V
19013	TMS29F002RT-12BFML	T.I.	262144 BY 8-BIT FLASH MEMORIES	32P/PLCC	2M	26144*8	120ns	5V
19014	TMS29F040-12C5DDE	T.I.	524288 BY 8-BIT FLASH MEMORY	32P/TSOP	4M	524288*8	120ns	5V
19017	TMS29F040-12C5DDL	T.I.	524288 BY 8-BIT FLASH MEMORY	32P/TSOP	4M	524288*8	120ns	5V
19018	TMS29F040-12C5FME	T.I.	524288 BY 8-BIT FLASH MEMORY	32P/PLCC	4M	524288*8	120ns	5V
19019	TMS29F040-90C5DDE	T.I.	524288 BY 8-BIT FLASH MEMORY	32P/TSOP	4M	524288*8	90ns	5V
19020	TMS29F040-90C5DDL	T.I.	524288 BY 8-BIT FLASH MEMORY	32P/TSOP	4M	524288*8	90ns	5V
19021	TMS29F040-90C5FML	T.I.	524288 BY 8-BIT FLASH MEMORY	32P/PLCC	4M	524288*8	90ns	5V
10946	W29C011A-15	WINBOND	128K x 8 CMOS flash memory	32P/DIP	1Mb	128K x 8	150ns	5V
14148	W29C020C-90B	WINBOND	256K x 8 CMOS FLASH MEMORY	32P/DIP	2M	256K*8	90ns	5V
46408	W29C020C-90Z	WINBOND	快闪式记忆体	DIP-32	2M	256K*8	90ns	
11825	W29C020CP-90B	WINBOND	256K*8 CMOS flash memory	32P/PLCC	2M	256K*8	90ns	5V
46409	W29C020CP90Z	WINBOND	256K*8 CMOS STATIC RAM	PLCC-32	2M	256*8	90	
19023	W29C020CT-90B	WINBOND	128K*8 CMOS flash memory	32P/TSOP	2M	128K*8	90ns	5V
10947	W29C040-90B	WINBOND	512K*8 CMOS flash memory	32P/DIP	4Mb	512K*8	90ns	5V
46459	W29C040-90Z	WINBOND	快闪式记忆体	DIP-32P	4M	512K*8	90ns	12
17704	W29C040P-70B	WINBOND	512K*8 CMOS flash memory	32P/PLCC	4Mb	512K*8	70ns	5V
22881	W29C040P-90B	WINBOND	512K*8 CMOS flash memory	32P/PLCC	4Mb	512K*8	90ns	5V
19024	W29EE011P-90	WINBOND	128K*8 CMOS flash memory	32P/PLCC	1M	128K*8	90ns	5V
33546	W39L040P-70B	WINBOND	512K*8 CMOS FLASH MEMORY	32P/PLCC	4Mbit	512K*8	70ns	3.3V

## 动态式记忆体 D-RAM

详细产品规格 - 请点击 [cn.100y.com.tw](http://cn.100y.com.tw)



100Y 编号	厂商编号	制造厂商	说明	Organisation	Package
48597	KM4164B-12	SAMSUNG	64K x 1-bit Dynamic Nmos Ram	64k x 1-bit	16P/DIP
48547	LH21256-10	SHARP	DRAM		16P/DIP
48503	LH21256-12	SHARP	DRAM		16P/DIP
48605	M5K4164ANP-15	MITSUBISHI	64K x 1-bit Dynamic Nmos Ram	64k x 1-bit	16P/DIP
48516	MB81256-10	FUJITSU	DRAM		16P/DIP



服务专线: 台湾: 886-3-5753170

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E-mail: 台湾: sale@100y.com.tw

深圳: 86-755-83298787

深圳: 86-755-83640655

深圳: 100y@163.com

上海: 86-21-34123367 & 54151736 37-16

上海: 86-21-64605107

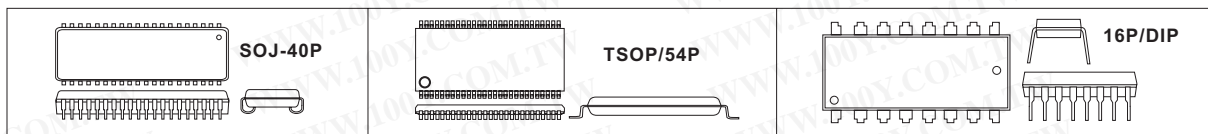
上海: 100y-1@163.com





## D-RAM

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100Y 编号	厂商编号	制造厂商	说明	Pins	Size (bits)	Organisation	Access Time	Package
48548	MSM3764A-15	OKI Semi	65536-WORD x 1-BIT DYNAMIC RAM				150ns	16P/DIP
48615	HM538123BJ-8	HITACHI	日立_1M VRAM (128-KWORD*8-BIT)	40P	8-BIT	128-KWORD*8-BIT	80 ns	SOJ-40P
23413	HY57V281620HCT-7	HYNIX	Synchronous DRAM	54P		4 Banks*2M*16bits	143MHz	TSOP
40587	HY57V561620CTP-H	HYNIX	静态式记忆体	54P	256Mb	4Banks x 4Mbits x16Bit		TSOP II
47658	HY57V561620FTP-H	HYNIX	动态式记忆体	54P	133MHZ	4 Banks*16M*16bits		TSOP
32823	IC42S32200-7T	ICS	SYNCHRONOUS DYNAMIC RAM	86P	512K Words x 32 Bits	64Mb Synchronous DRAM	143MHz	TSOP-2
22625	IS42S16100-7T	ISSI	SYNCHRONOUS DYNAMIC RAM	50P	512K*16bits	16Mb Synchronous DRAM	166, 143, 100 MHz	TSOP
28954	K4S561632E-TC75	SAMSUNG	静态式记忆体		256Mb	16M x 16		TSOP
23593	MSM514400D-60SJ	OKI Semi	DYNAMIC RAM	26P	1,048,576* 4Bit		60ns	SOJ
48502	UPD41256-15	NEC	262144 x 1-bit Dynamic Nmos Ram			262144 x 1-bit		16P/DIP

